

ARPES on Electronic Structure and Superconductivity of FeSe /SrTiO₃ Films

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Ph. D Students: Daixiang MOU, Junfeng HE, Chaoyu CHEN, Yingying PENG, Xu LIU, Ya FENG, Zhuojin XIE, Yan LIU, Hemian YI, Yuxiao Zhang, Aiji LIANG, Defa LIU, Bing SHEN, Cheng HU, Chenlu WANG, Yan ZHANG, Xuan SUN, Yong HU, Ying DING, Jianwei HUANG, Wenjuan ZHAO



Colleagues and Collaborators

➤ ARPES System Development, Maintenance and Improvement;

Chuangtian Chen, Yong Zhu, Guochun Zhang, Xiaoyang Wang

Zuyan Xu, Guiling Wang, Hongbo Zhang, Yong Zhou

Technical Institute of Physics and Chemistry, CAS, China

➤ FeSe Thin Films on SrTiO₃ (001)

Wenhai Zhang, Yun-Bo Ou, Qing-Yan Wang, Zhi Li, Lili Wang,

Xucun Ma and **Qikun Xue**, Institute of Physics, CAS & Tsinghua University

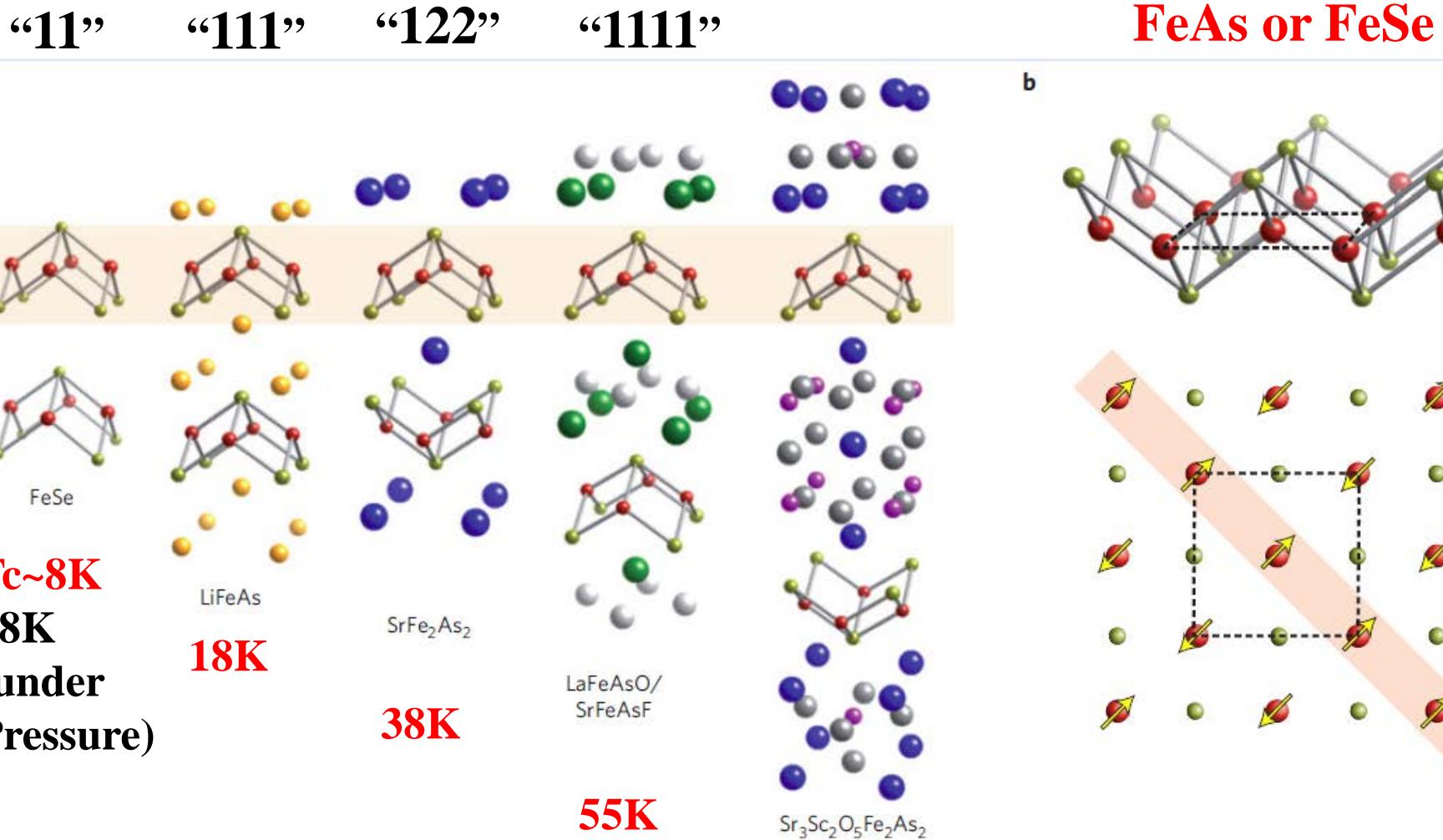
➤ Theoretical Discussions

Jiangping Hu, Dung-hai Lee, Qianghua Wang, Tao Xiang, Qimiao Si

Outline

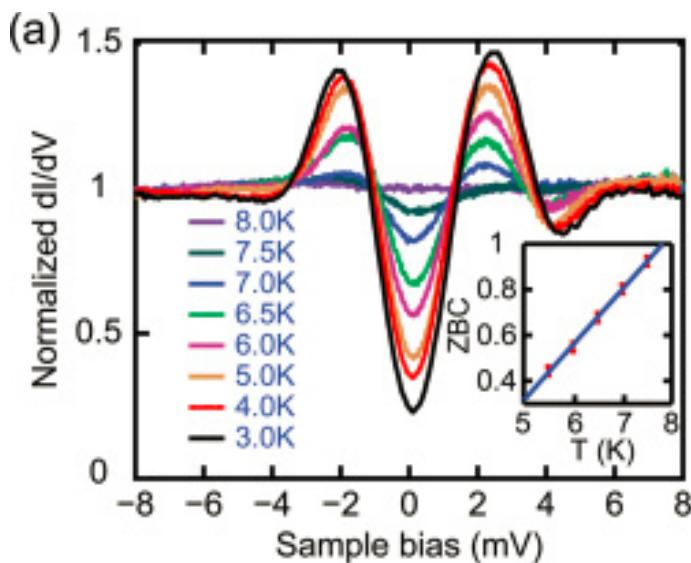
- **Distinct Electronic Structure of Superconducting Single-Layer FeSe/SrTiO₃ Films;**
- **Electronic Phase Diagram of Single-Layer FeSe/SrTiO₃ Films;**
- **Evidence of an Insulator-Superconductor Transition in Single-Layer FeSe/SrTiO₃ Films;**
- **Dichotomy between the Single-Layer and Double-Layer FeSe/SrTiO₃ Films.**

Iron-Based Superconductors

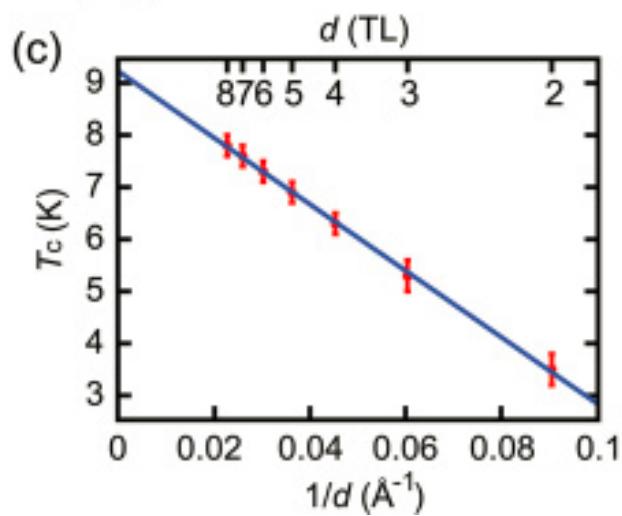
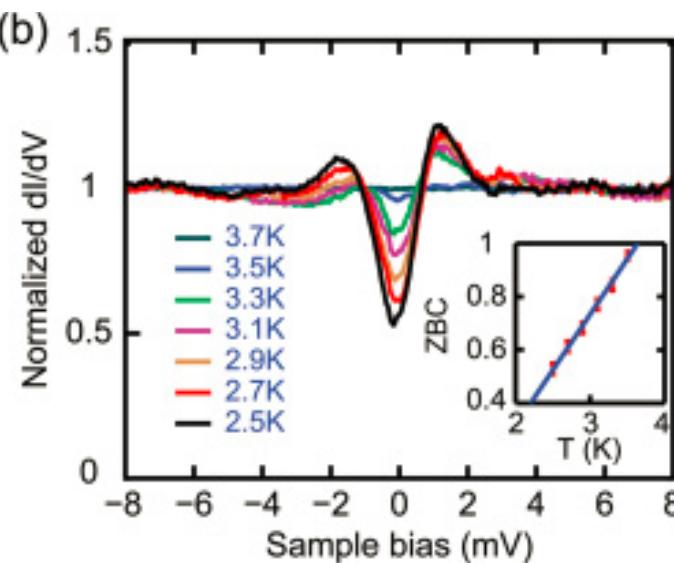


FeSe Films Grown on Graphene

8-Layer



2-Layer



Possible High T_c in Single-Layer FeSe Film on SrTiO₃

CHIN. PHYS. LETT. Vol. 29, No. 3 (2012) 037402

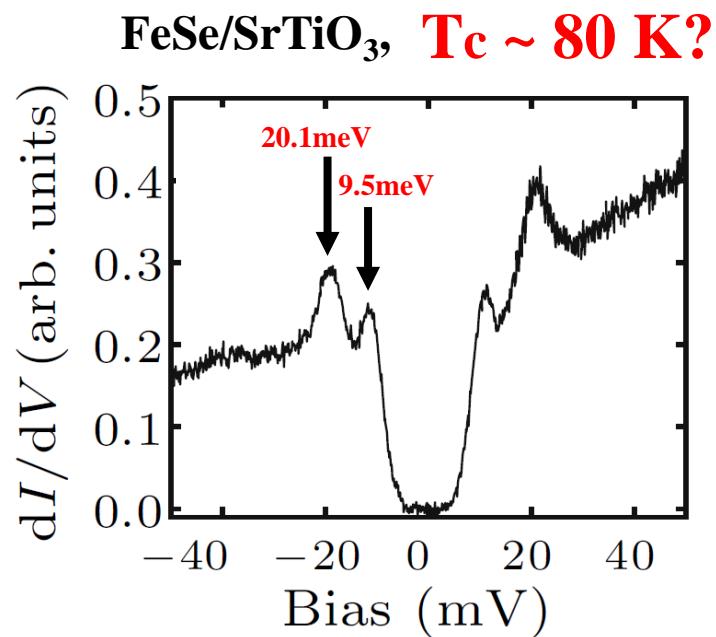
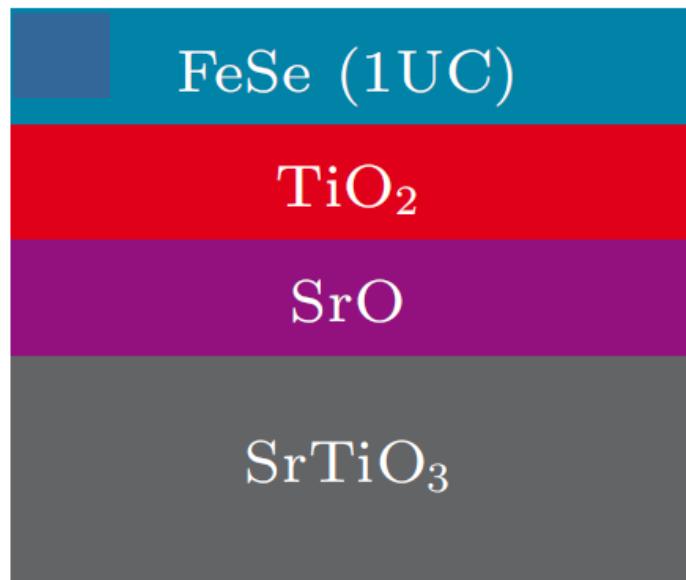
Interface-Induced High-Temperature Superconductivity in Single Unit-Cell FeSe Films on SrTiO₃ *

WANG Qing-Yan(王庆艳)^{1,2†}, LI Zhi(李志)^{2†}, ZHANG Wen-Hao(张文号)^{1†}, ZHANG Zuo-Cheng(张祚成)^{1†}, ZHANG Jin-Song(张金松)¹, LI Wei(李渭)¹, DING Hao(丁浩)¹, OU Yun-Bo(欧云波)², DENG Peng(邓鹏)¹, CHANG Kai(常凯)¹, WEN Jing(文竞)¹, SONG CanLi(宋灿立)¹, HE Ke(何珂)², JIA Jin-Feng(贾金锋)¹, JI Shuai-Hua(季帅华)¹, WANG Ya-Yu(王亚愚)¹, WANG Li-Li(王立莉)², CHEN Xi(陈曦)¹, MA Xu-Cun(马旭村)^{2***}, XUE Qi-Kun(薛其坤)^{1***}

¹State Key Lab of Low-Dimensional Quantum Physics, Department of Physics, Tsinghua University, Beijing 100084

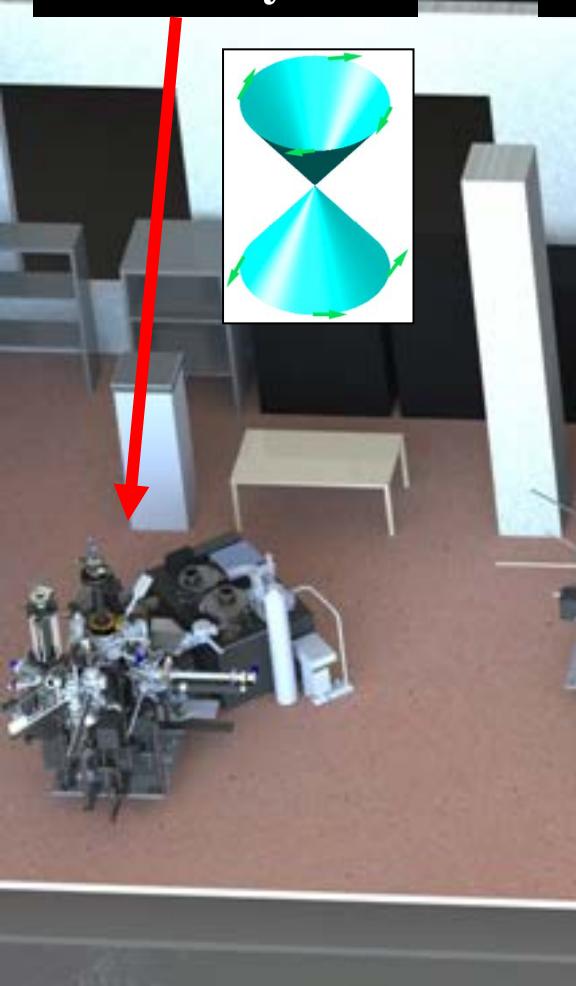
²Institute of Physics, Chinese Academy of Sciences, Beijing 100190

(Received 1 February 2012 and accepted by ZHU Bang-Fen)

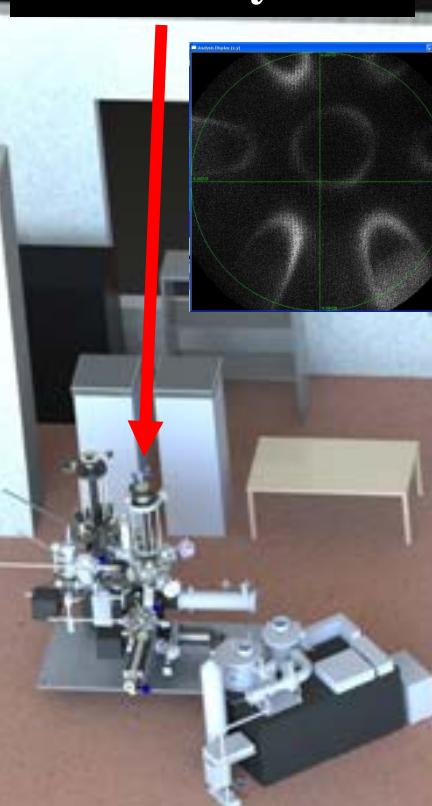


VUV Laser Photoemission Lab at IOP

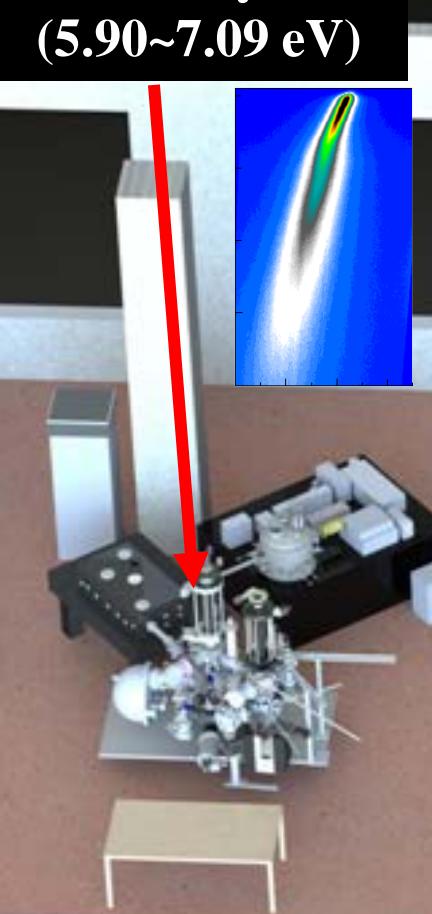
Spin-Resolved
ARPES system



2-D Momentum
ARPES system



Tunable Laser
ARPES system
(5.90~7.09 eV)



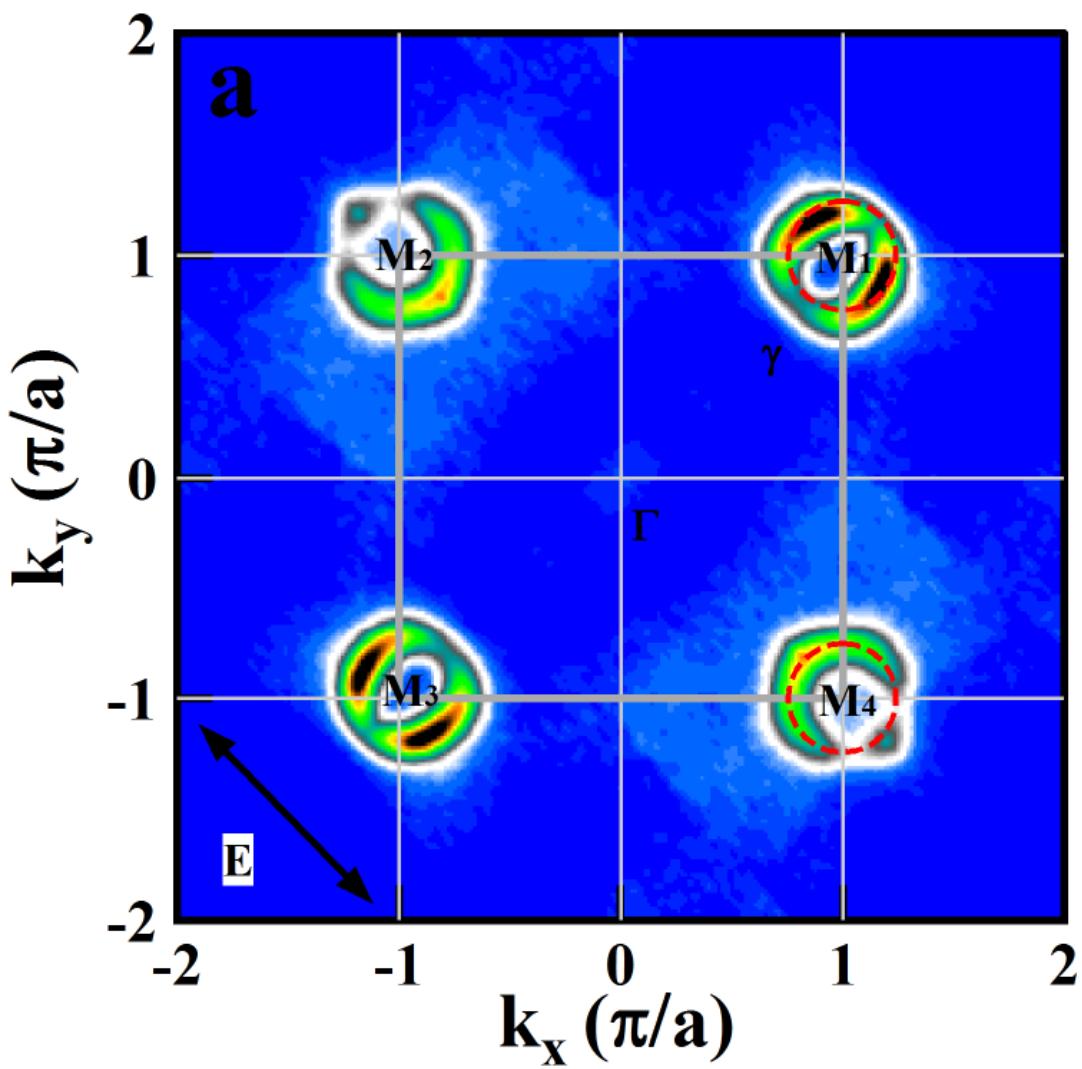
He 3 (<1K)
ARPES system
(under construction)



ARPES on Single-Layer Superconducting FeSe/SrTiO₃

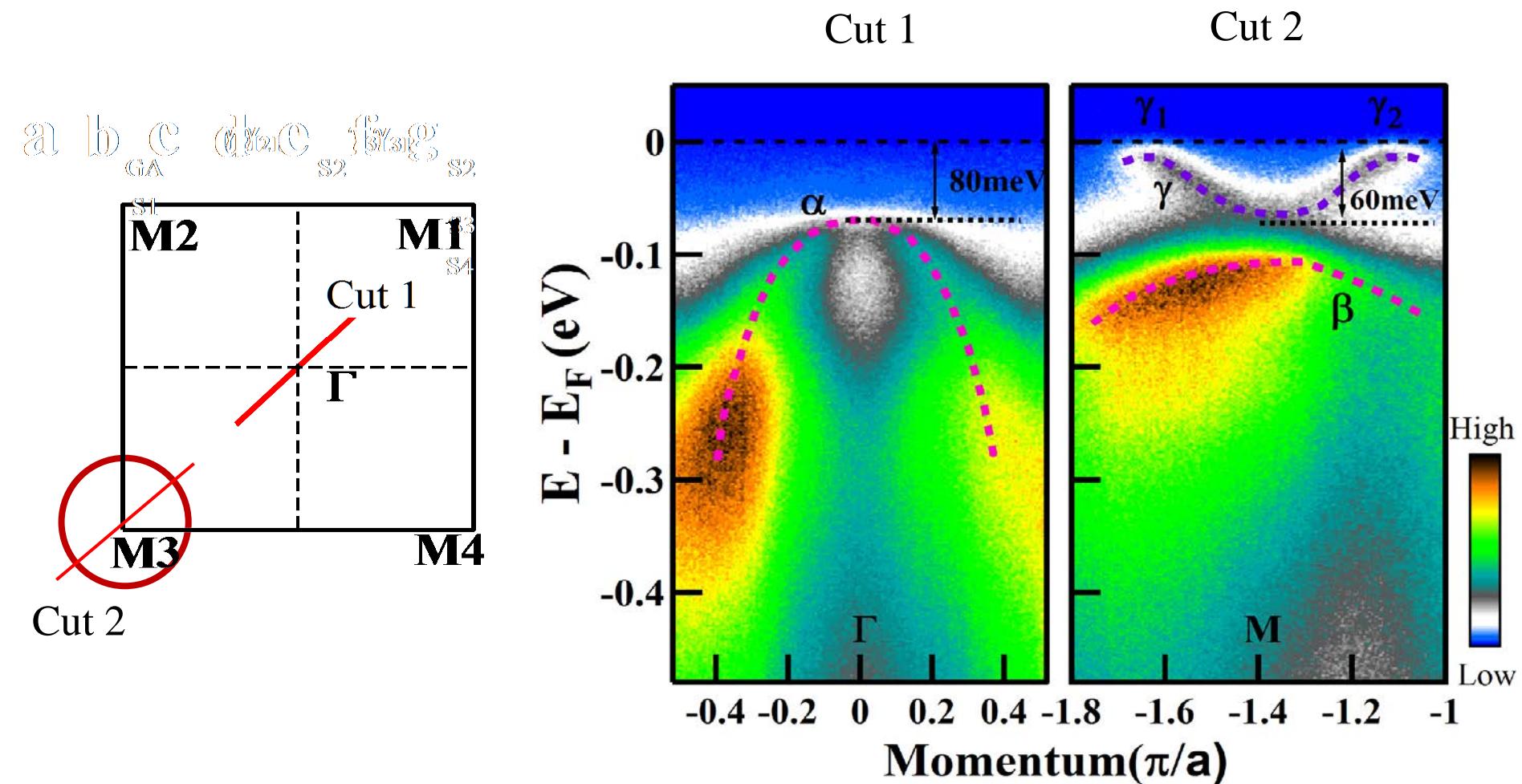
D. F. Liu , W. H. Zhao, D. X. Mou, J. F. He, X. C. Ma, Q. K. Xue, X. J. Zhou et al.,
Nature Communications 3, 931 (2012).

Fermi Surface of Single-Layer Superconducting FeSe/SrTiO₃



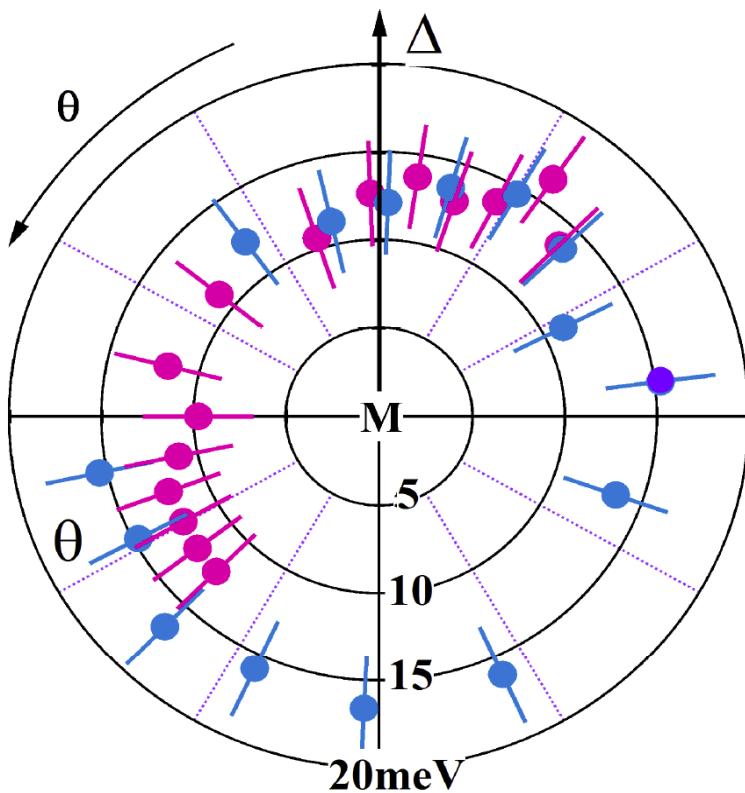
- Only one Fermi surface γ around M ;
- No signature of any Fermi surface around Γ .

Band Structure of Single-Layer Superconducting FeSe/SrTiO₃



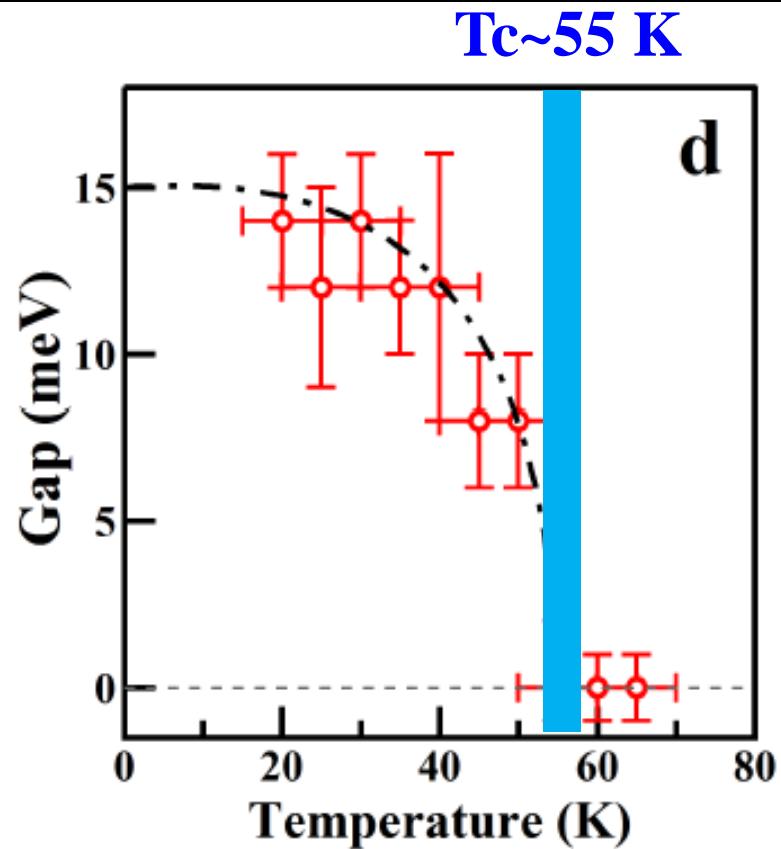
D. F. Liu , W. H. Zhao, D. X. Mou, J. F. He, X. C. Ma, Q. K. Xue, X. J. Zhou et al.,
Nature Communications 3, 931 (2012).

Momentum and Temperature Dependence of the Energy Gap



Nearly isotropic energy gap;

2D Character → No Gap Node.

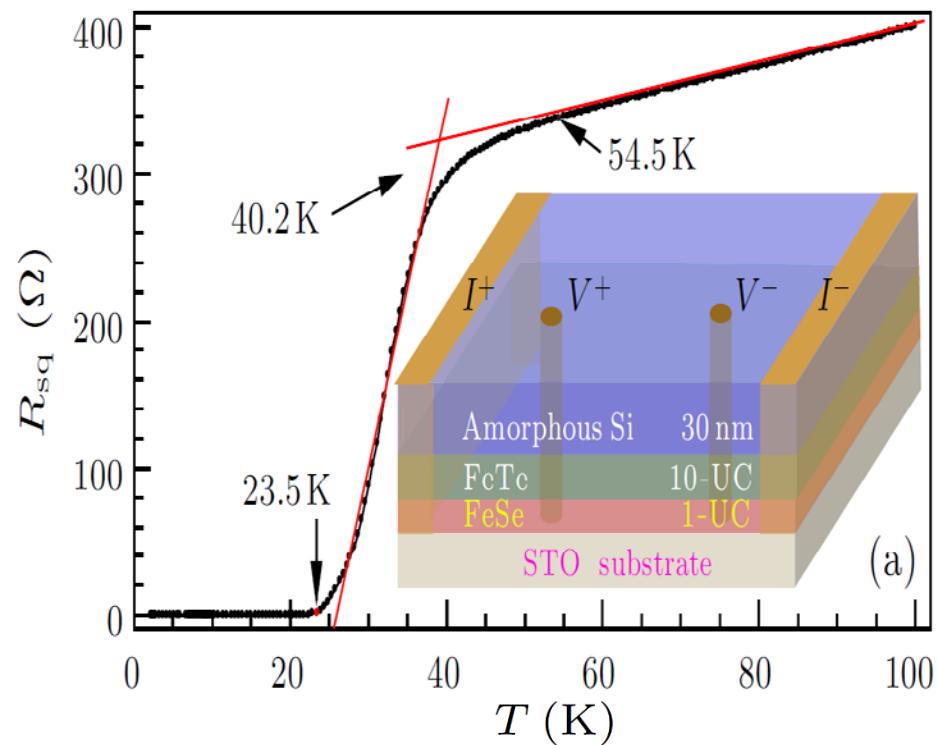


Nearly BCS form;

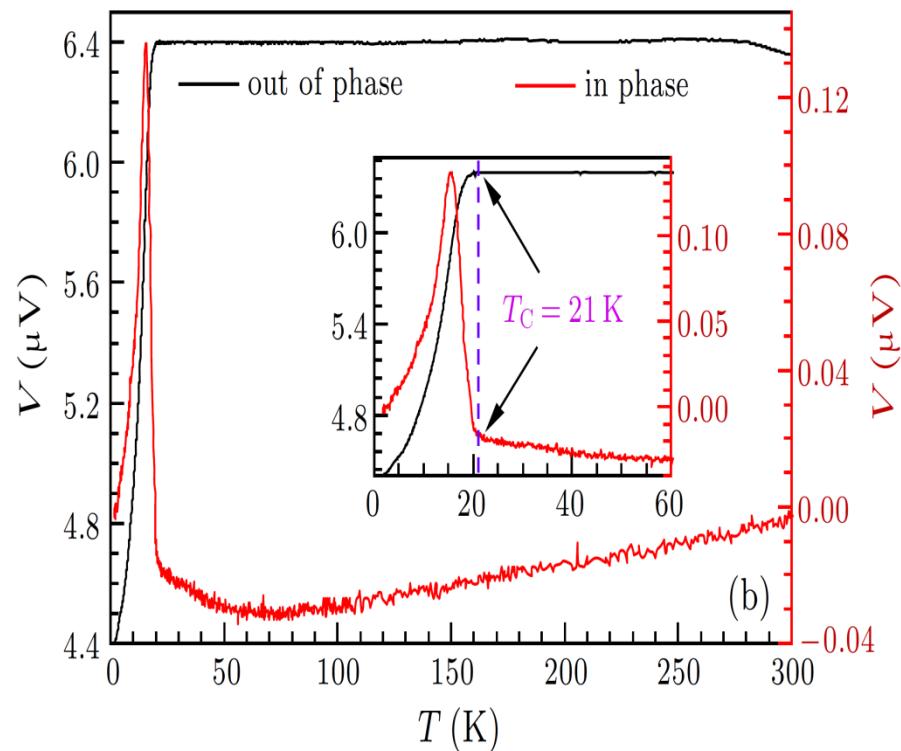
Tc~55K.

Transport and Magnetic Measurements on Single-Layer FeSe/SrTiO₃ Films

Resistivity



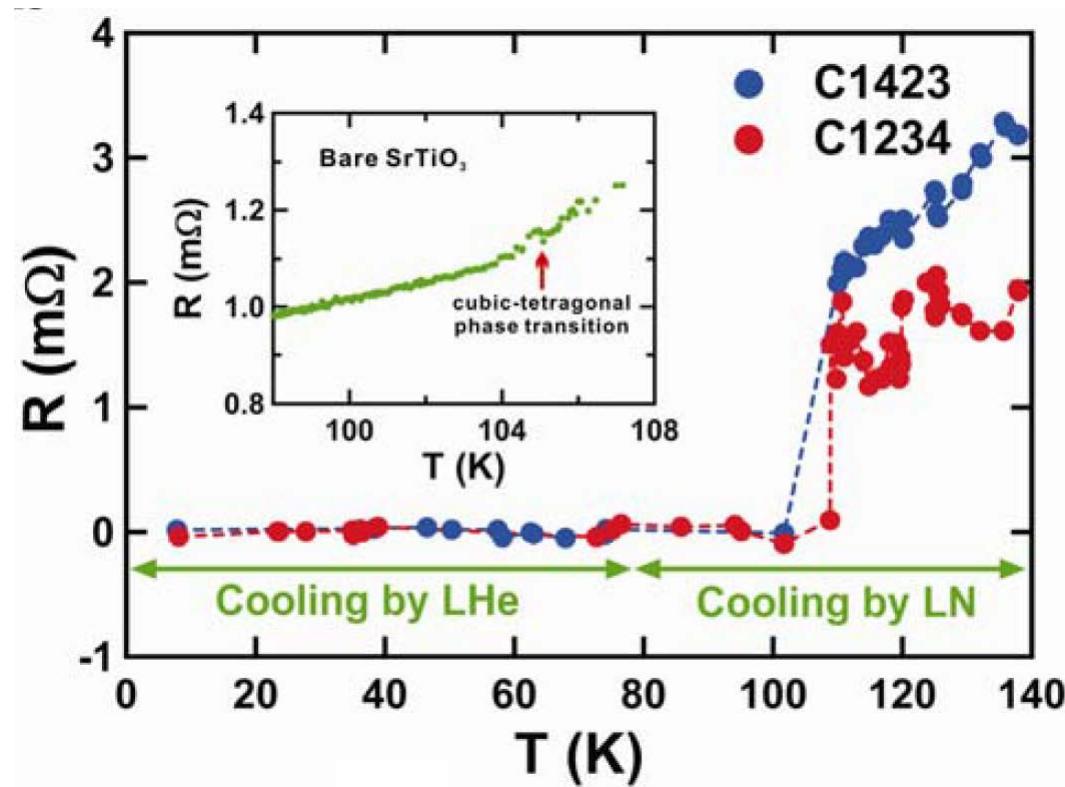
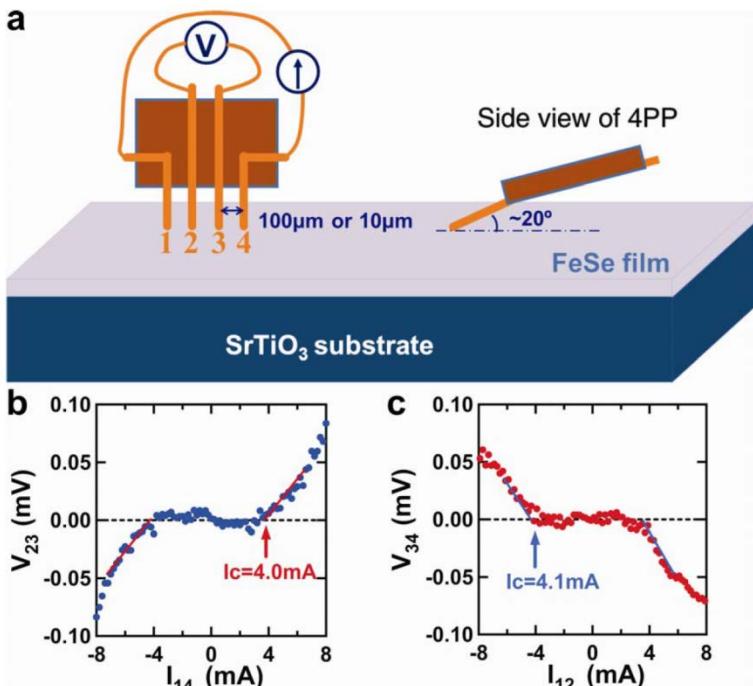
Magnetism



W. H. Zhang, J. Wang, X. C. Ma, Q. K. Xue et al.,
Chinese Physics Letters 31 (2014) 017401.

Superconductivity in single-layer films of FeSe with a transition temperature above 100 K

Jian-Feng Ge¹, Zhi-Long Liu¹, Canhua Liu^{1*}, Chun-Lei Gao¹, Dong Qian¹, Qi-Kun Xue^{2*}, Ying Liu^{1,3}, Jin-Feng Jia^{1*}



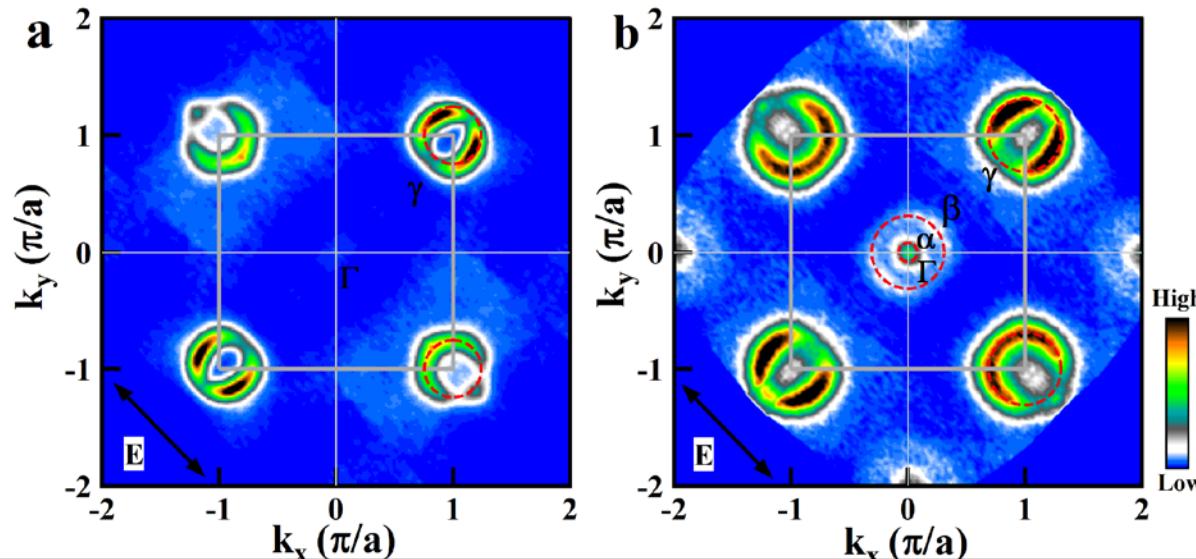
arXiv: 1406.3435

Fermi Surface Topology of the Iron-Based Superconductors

Class I

Single-Layer
FeSe
 $T_c \sim 65$ K

D. F. Liu et al.,
Nature Commun.
3(2012)931.



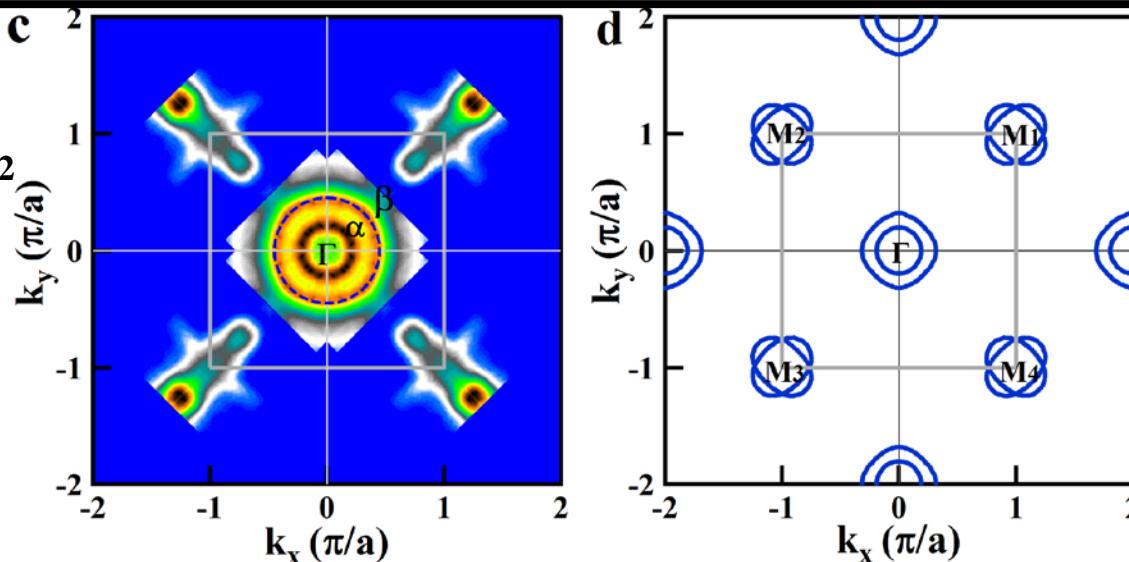
$A_xFe_{2-y}Se_2$
 $T_c \sim 32$ K

D. X. Mou et al.,
Phys. Rev. Lett.
6 (2011) 410.

Class II

$(Ba_{0.6}K_{0.4})Fe_2As_2$

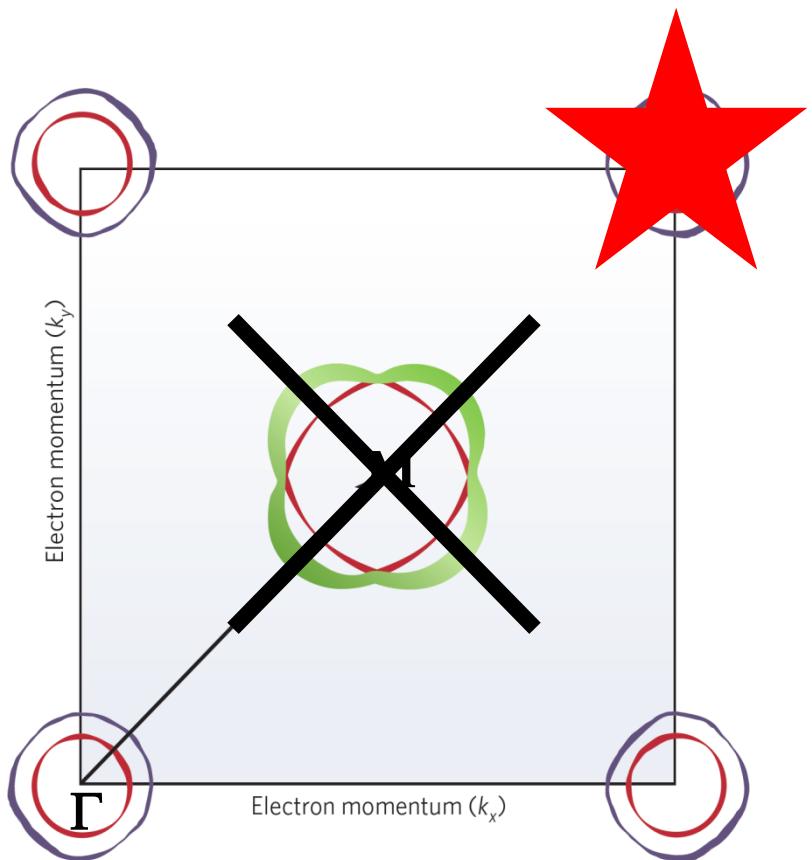
L. Zhao et al.,
Chin. Phys. Lett.
25 (2008) 4402.



Bulk
 $Fe(Se,Te)$

A. Tamai et al.,
Phys. Rev. Lett.
104 (2010) 097002.

Implications



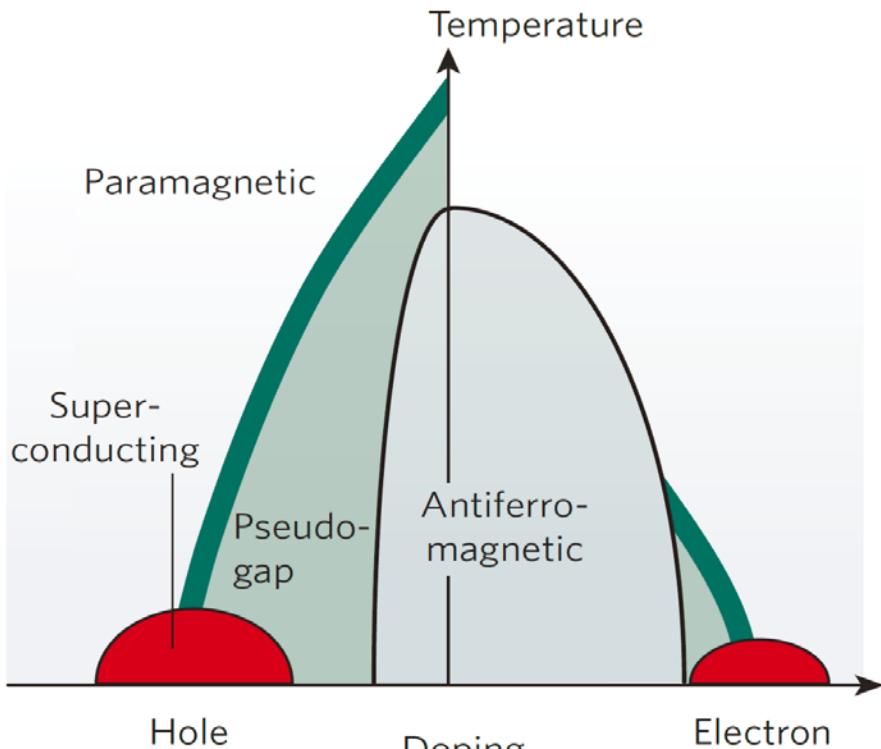
1. Fermi surface topology is not critical to superconductivity?
2. If it is critical, then Hole-Like Fermi Surface near Γ is NOT important;
Electron-Like Fermi Surface near M is crucial.

Phase Diagram and Electronic Indication of Superconductivity at 65K in Single-Layer FeSe/SrTiO₃

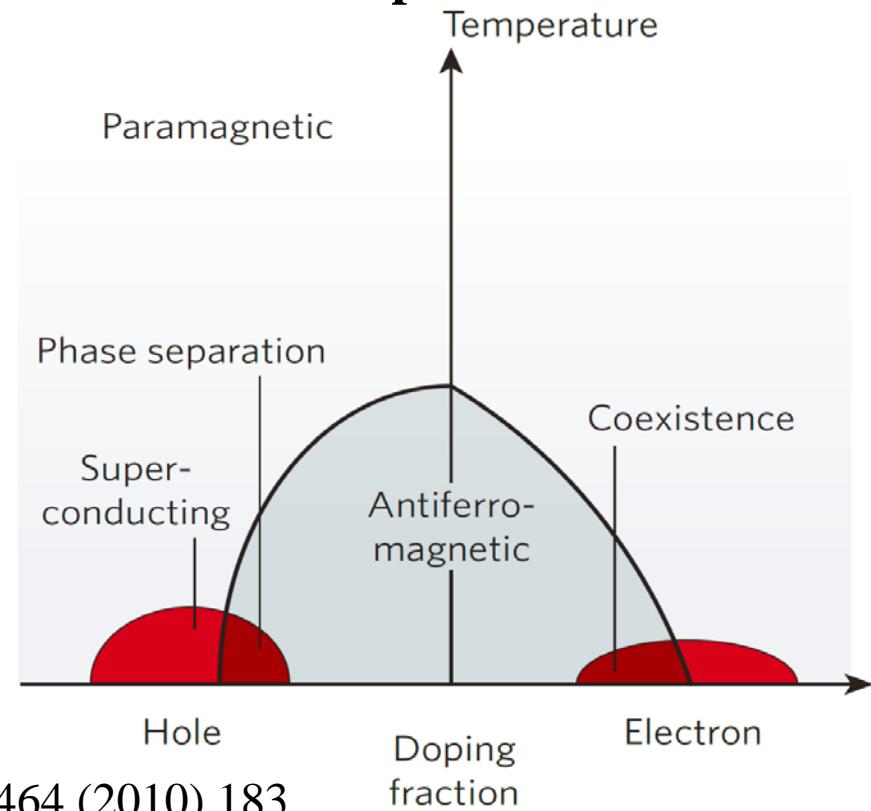
S. L. He, J. F. He, W. H. Zhang, L. Zhao, X. C. Ma, Q. K. Xue, X. J. Zhou et al.,
Nature Materials 12, 605 (2013).

Phase Diagram of High Temperature Superconductors

Cu-Based Superconductors



Fe-Based Superconductors



I. Mazin, Nature 464 (2010) 183.

1. Doping evolution of electronic structure in single-layer FeSe?
2. Can superconductivity of the single-layer FeSe be optimized?

MBE Preparation of FeSe Films: Two Steps

MBE Film Preparation

Step 1

As-prepared FeSe Films
grown at a low temperature
~300C
(Non-superconducting)



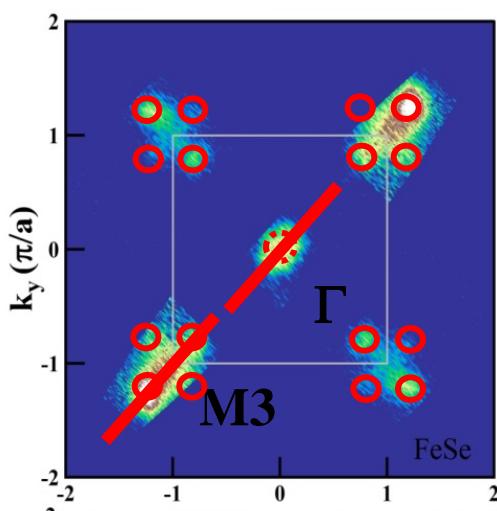
Step 2

FeSe Films
annealed at a high temperature
450-~500C
(Superconducting)

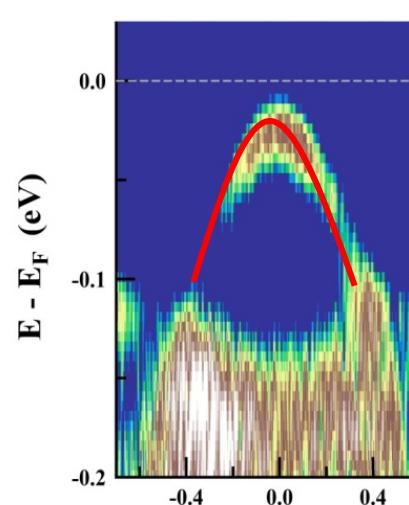
Electronic Structure of the *As-Prepared* Non-Superconducting Single-Layer FeSe/SrTiO₃ Films

“Fermi Surface” and Band Structure of Non-Superconducting Phase

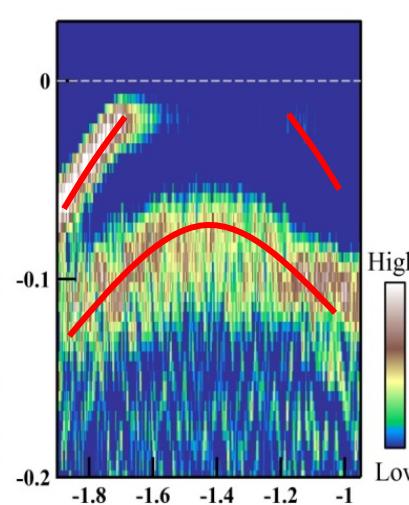
“Fermi Surface”



Γ Cut

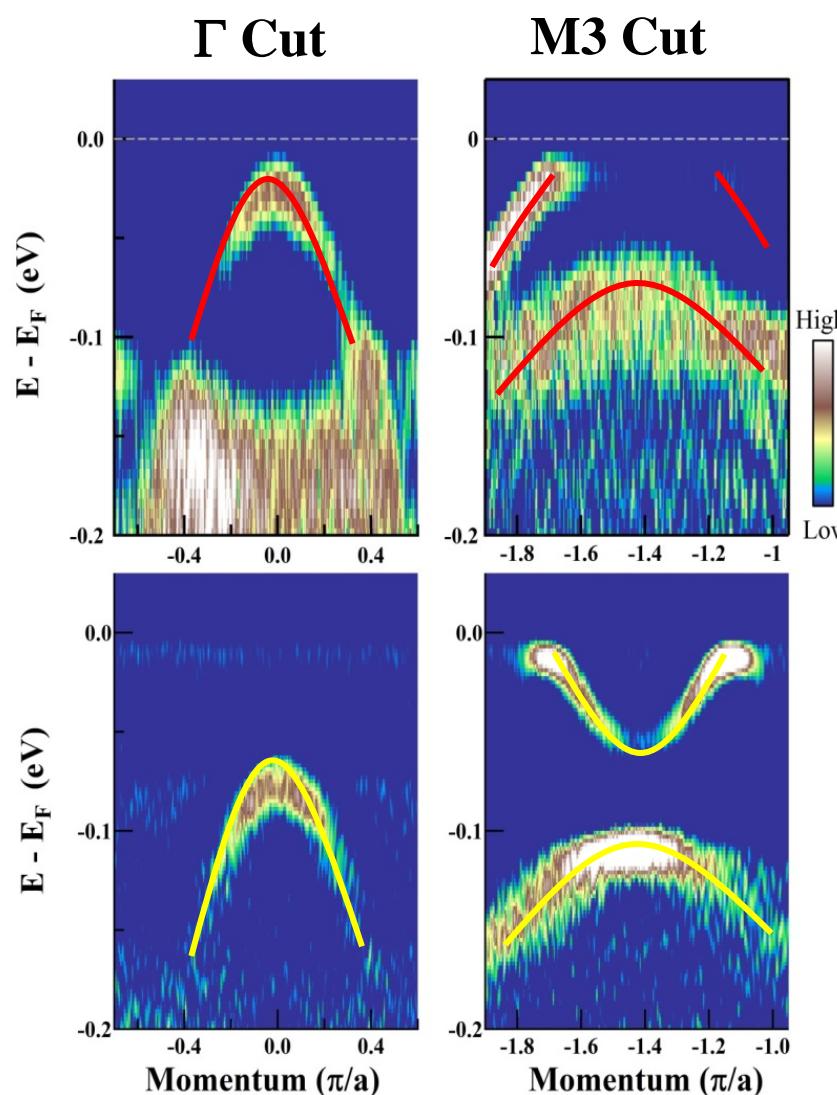
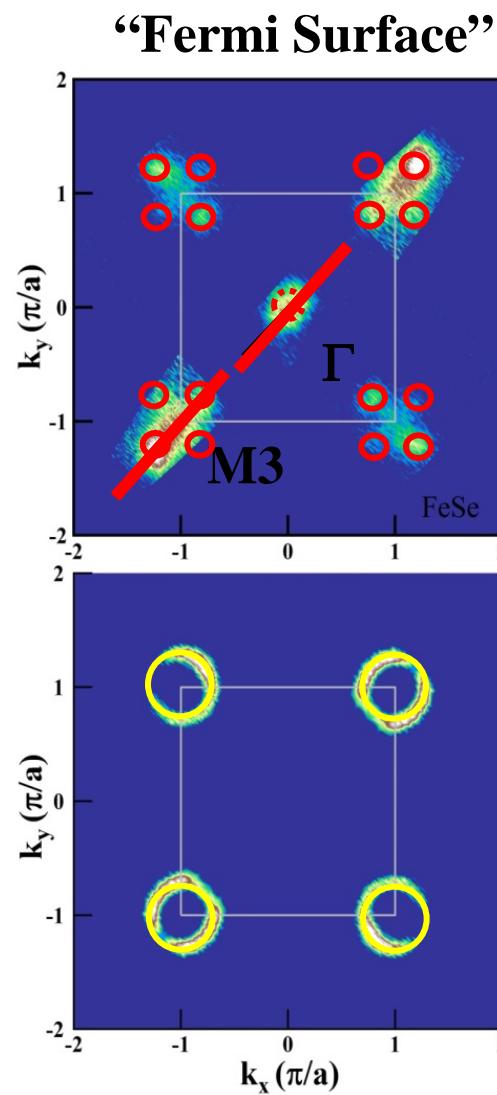


M3 Cut



As-prepared
Non-superconducting

Non-Superconducting vs Superconducting Phases



As-prepared
Non-superconducting

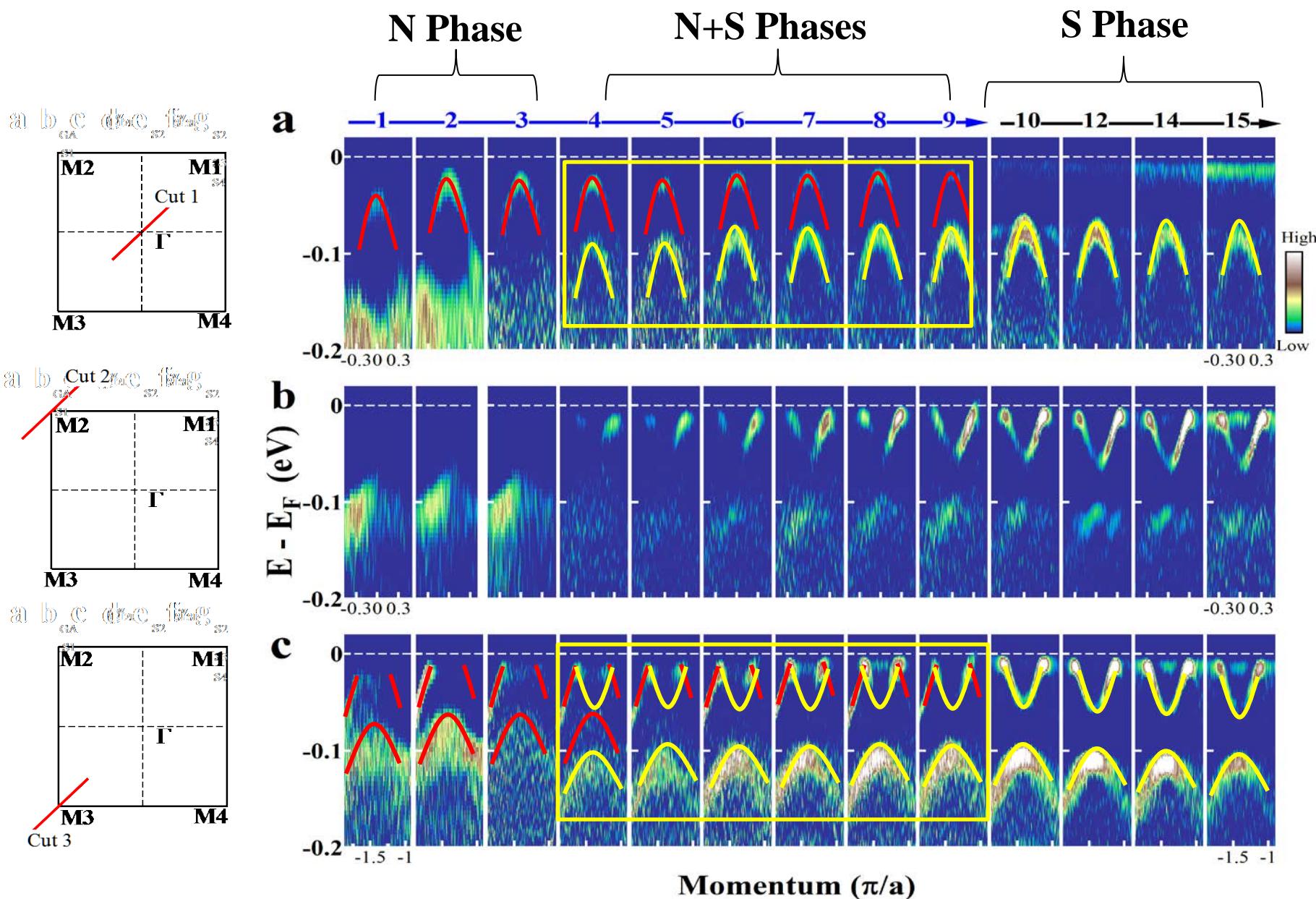
N Phase

Annealed
Superconducting

S Phase

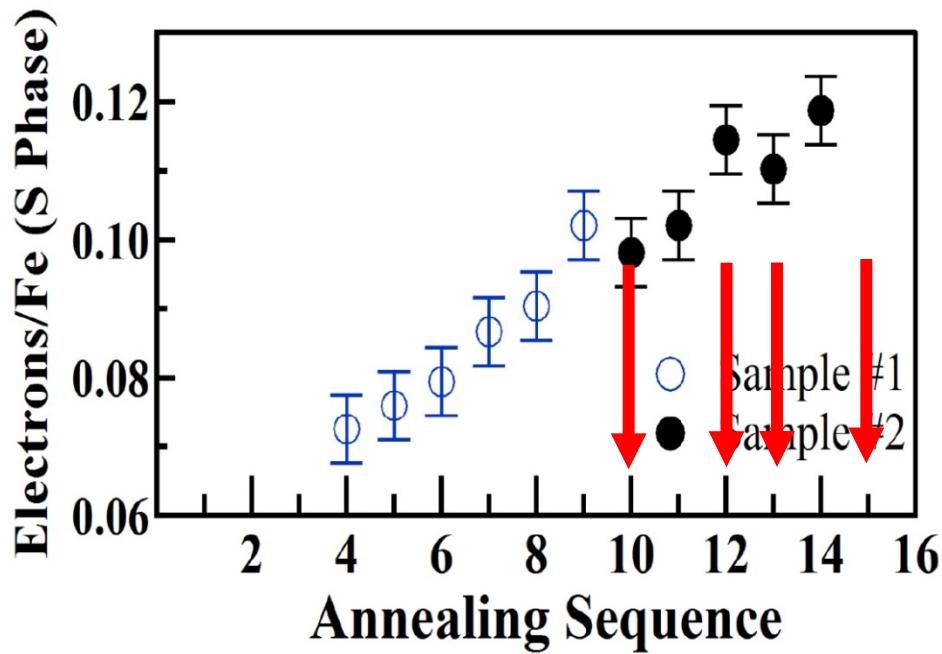
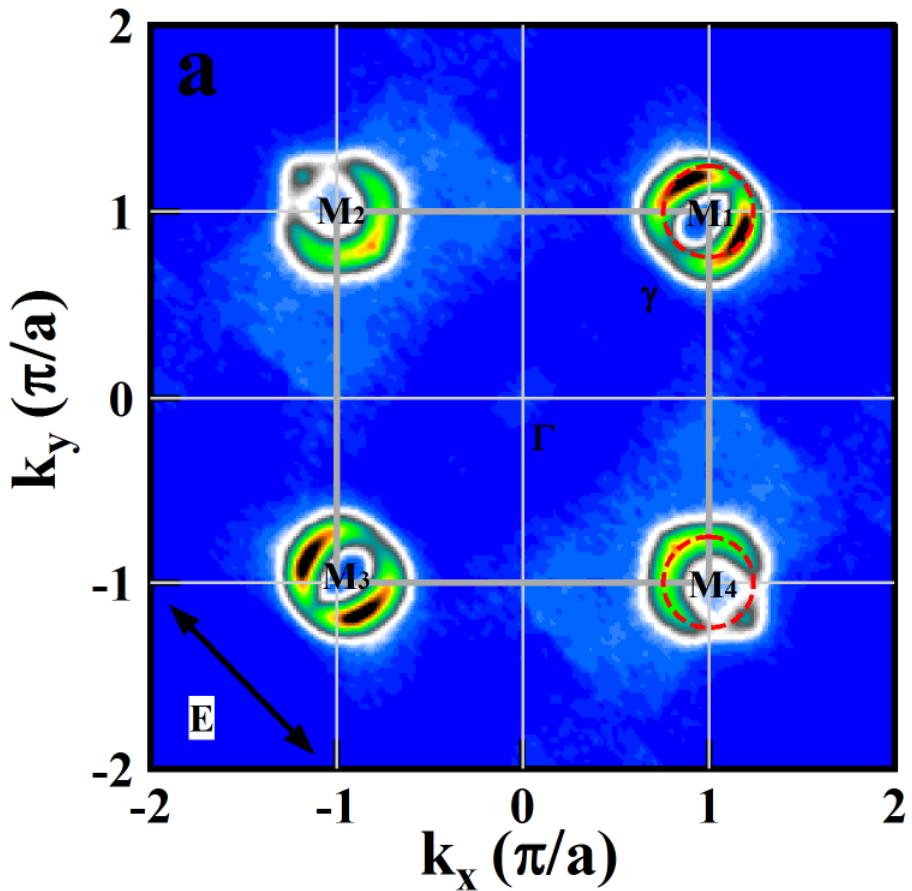
Evolution from N phase to S phase

Evolution of Band Structures with Annealing in Single-Layer FeSe/SrTiO₃



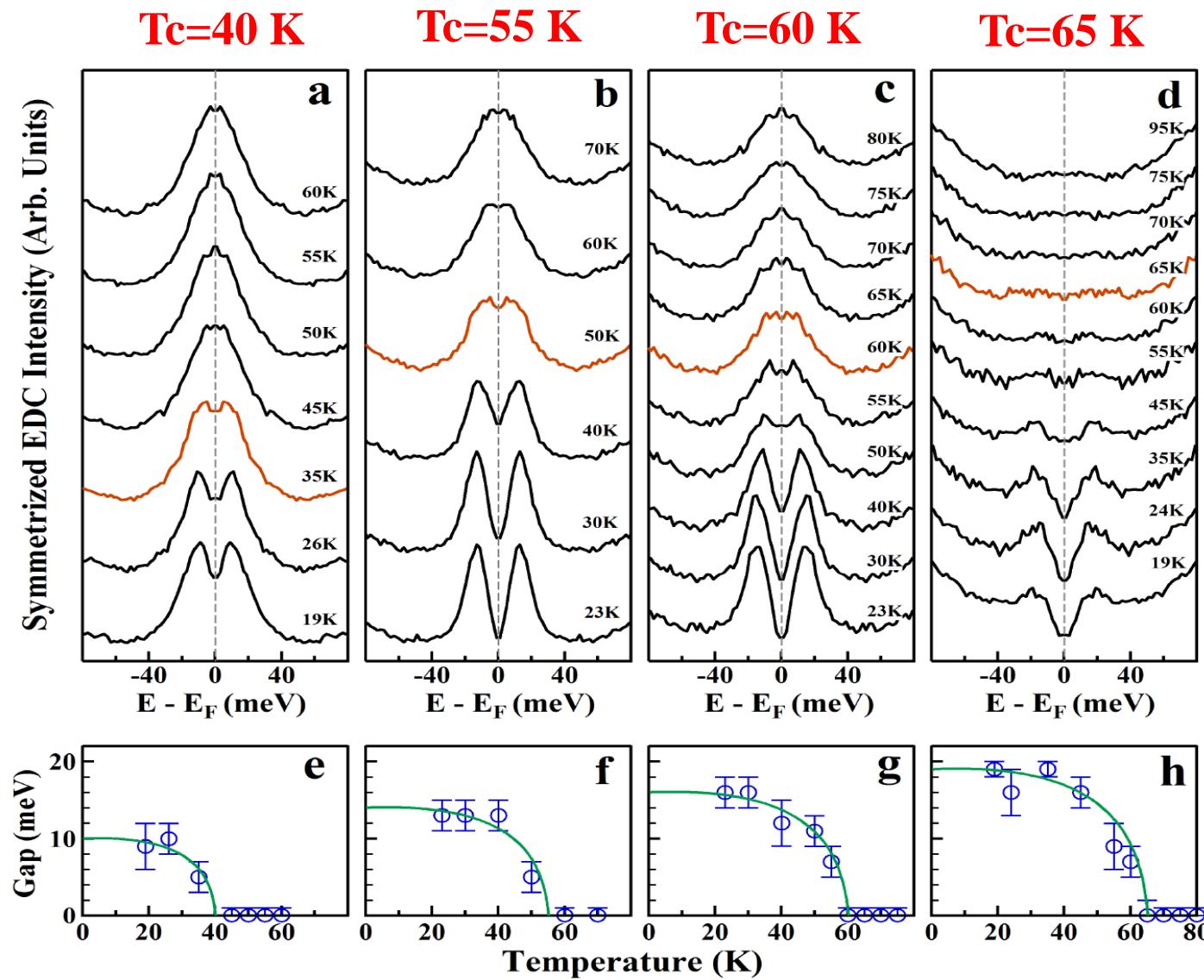
Doping-Evolution of Superconductivity in the S Phase.....

Electron Counting in S Phase in Single-Layer FeSe/SrTiO₃

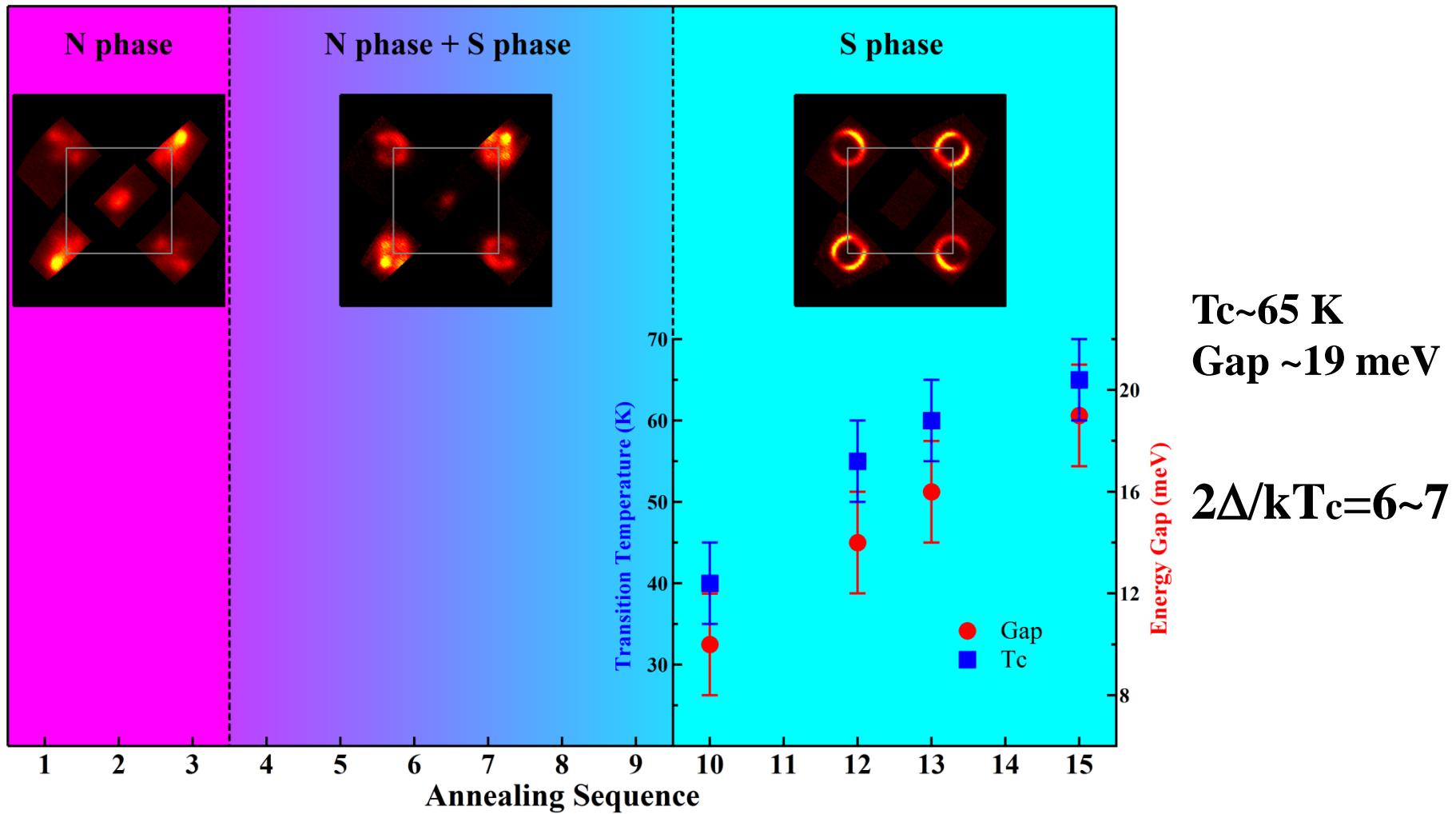


- S phase has only an electron-like Fermi surface sheet near M;
- Assuming two Fermi surface sheets near M.

Energy Gap of Single-Layer FeSe under Different Annealing Conditions

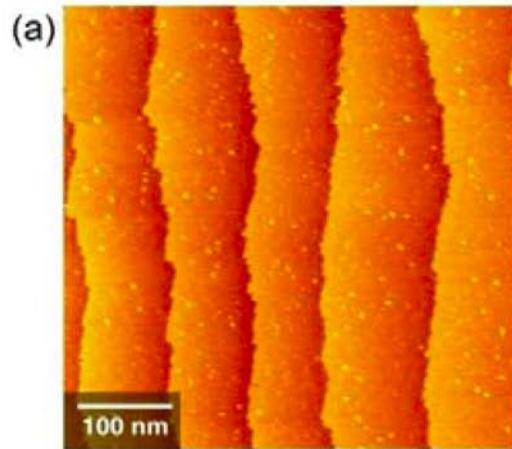


Phase Diagram of Single-Layer FeSe/SrTiO₃ Film

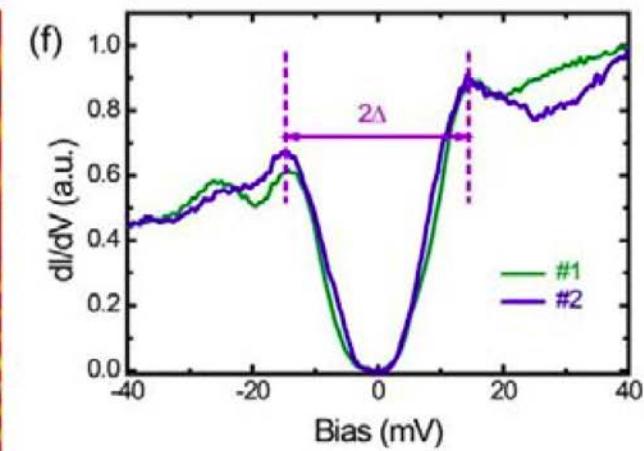
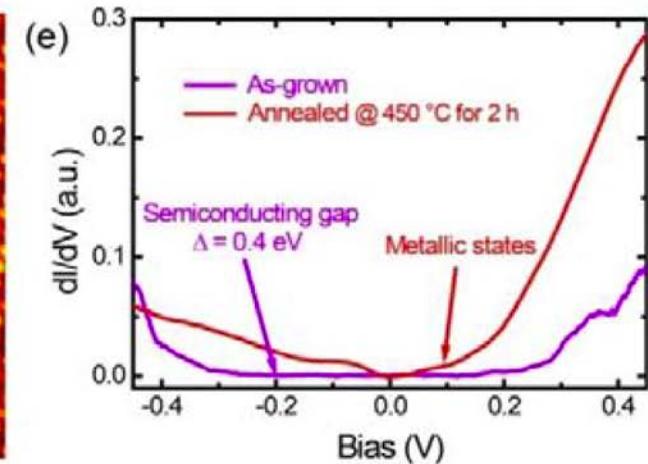
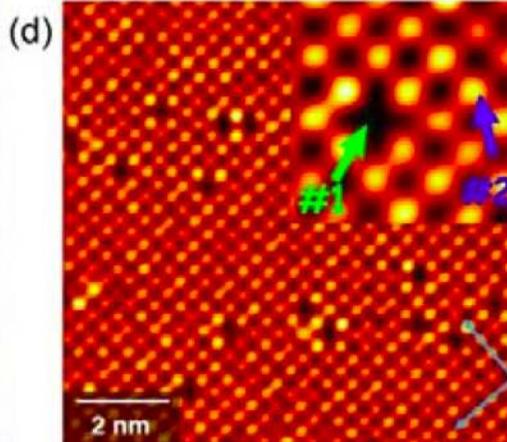
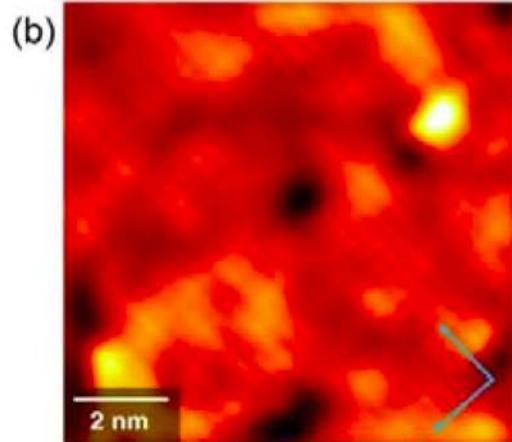
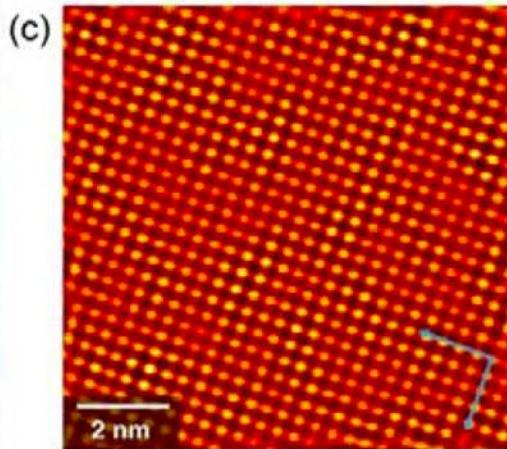


STM/STS on As-Prepared and Vacuum Annealed Single-Layer FeSe/SrTiO₃ Film

As-grown



Annealed at 400C/2hr

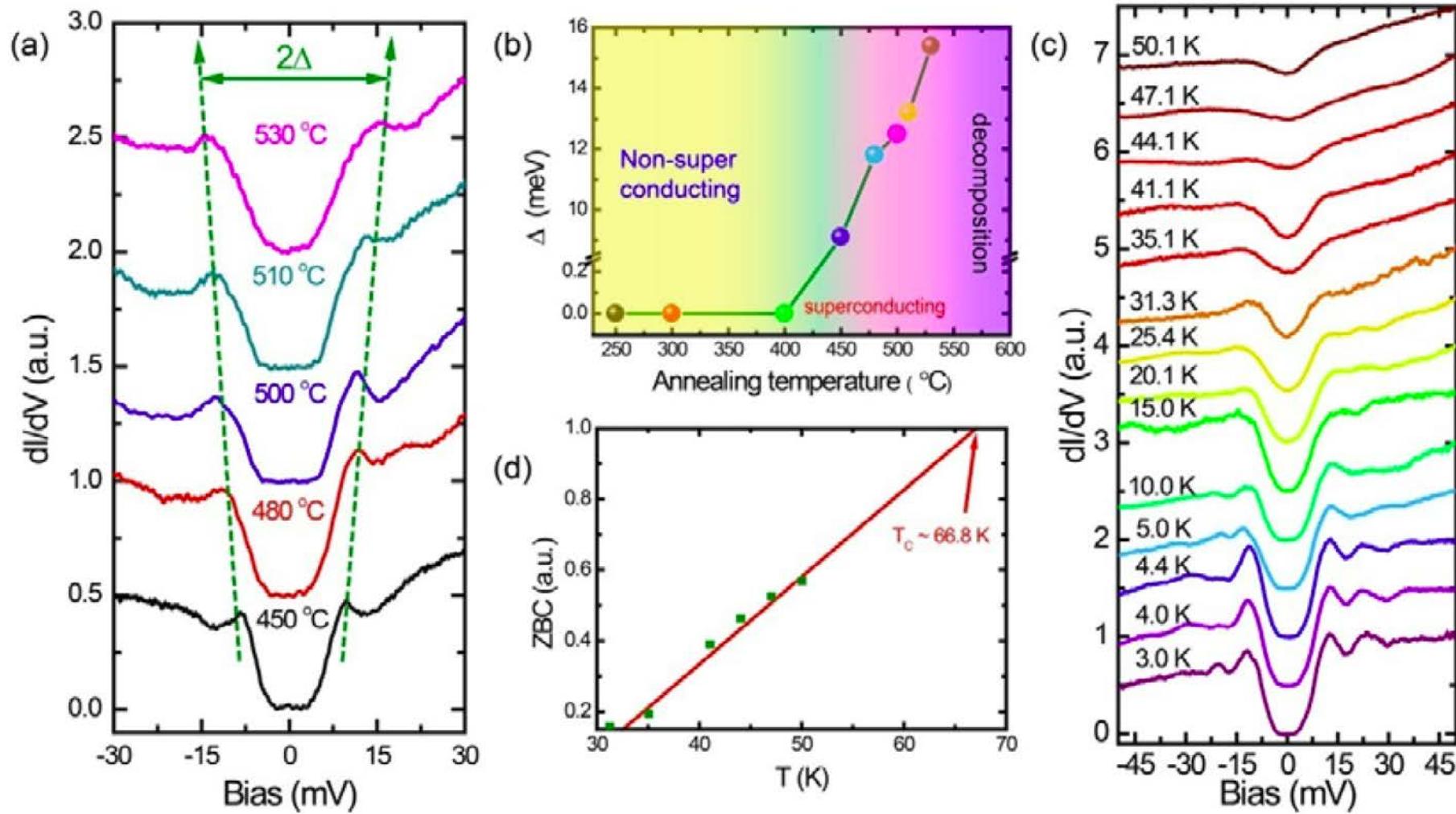


Annealed at 450C/2hr

Annealed at 530C/2hr

Wenhao Zhang, Zhi Li, Fangsen Li¹, Huimin Zhang, Junping Peng, Chenjia Tang, Ke He, Xi Chen, Lili Wang, Xucun Ma and Qi-Kun Xue, Phys. Rev. B 89, 060506(R) (2014)

Evolution with Annealing for Single-Layer FeSe/SrTiO₃ Film



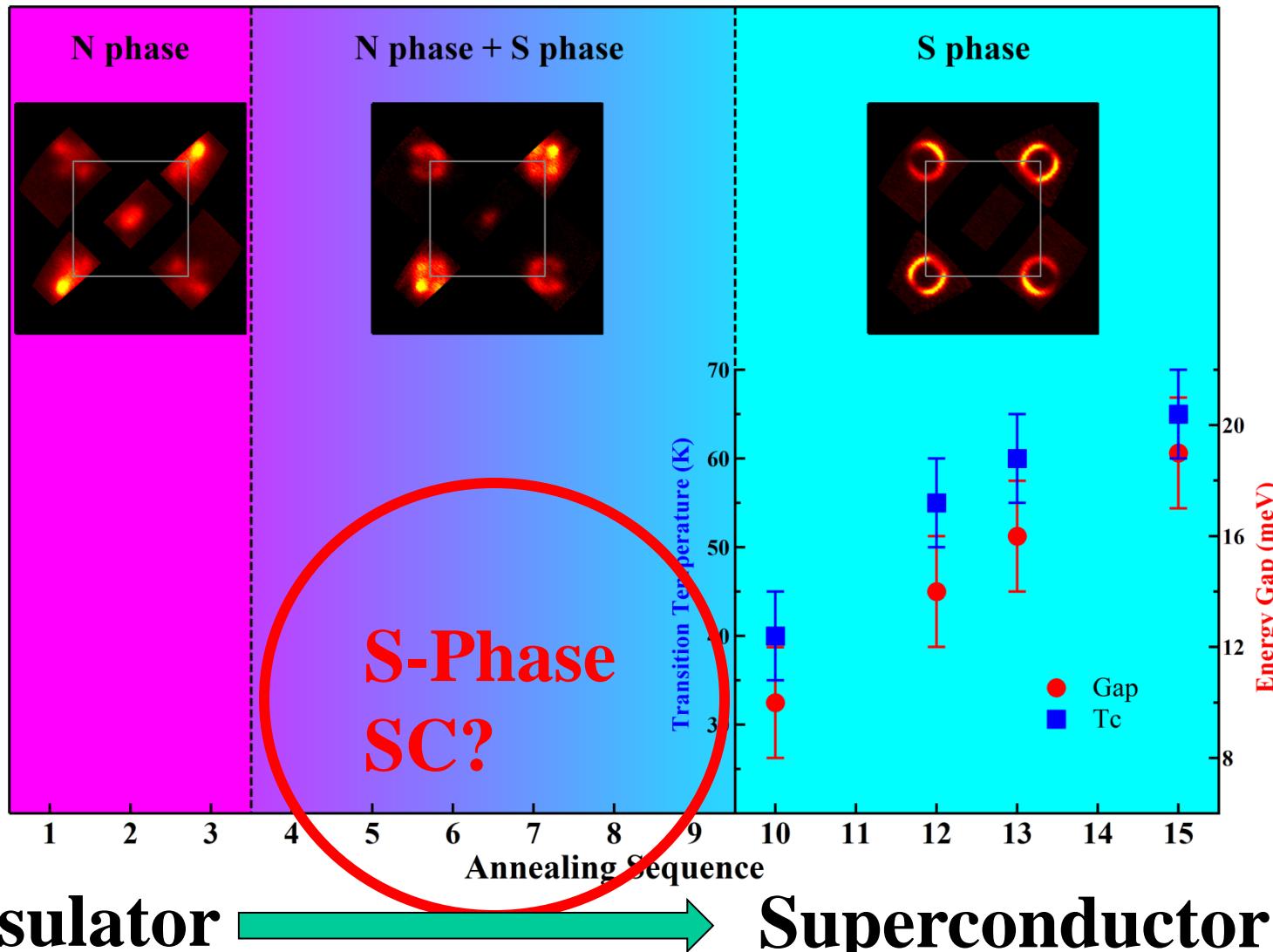
Wenhao Zhang, Zhi Li, Fangsen Li¹, Huimin Zhang, Junping Peng, Chenjia Tang, Ke He, Xi Chen, Lili Wang, Xucun Ma and Qi-Kun Xue, Phys. Rev. B 89, 060506(R) (2014)

Electronic Evidence of an Insulator-Superconductor Transition in Single-Layer FeSe/SrTiO₃ Films.

Junfeng He, Xu Liu, Wenhao Zhang, Lin Zhao, X. C. Ma, Q. K. Xue, X. J. Zhou et al.,

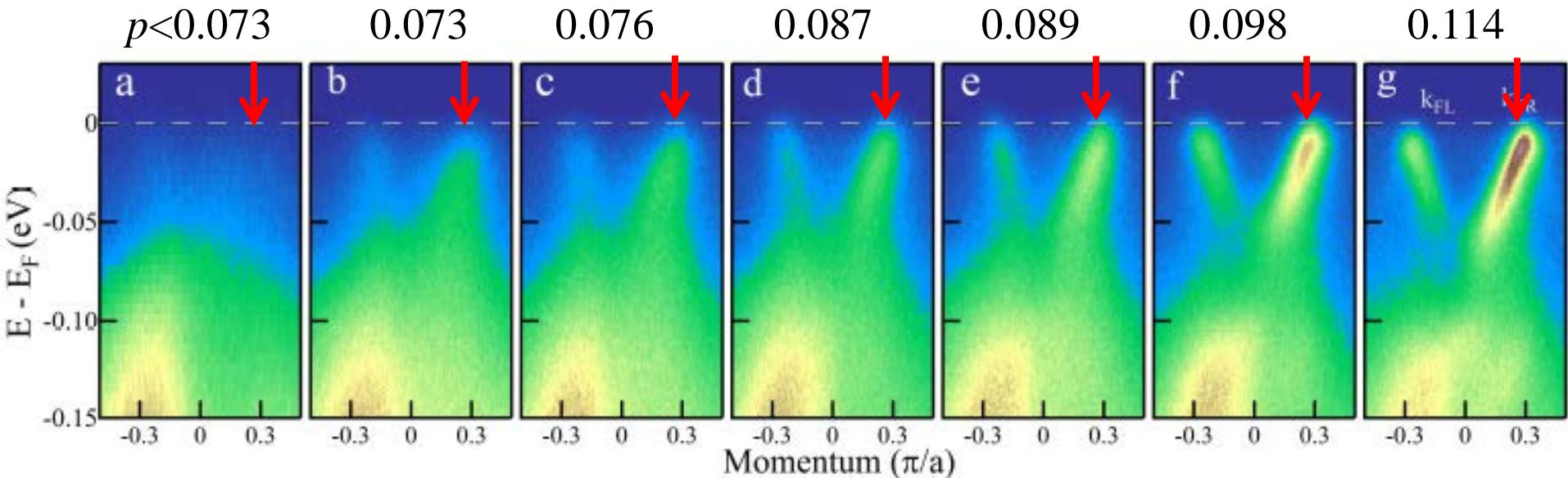
arXiv:1401.7115

Phase Diagram of Single-Layer FeSe/SrTiO₃ Film



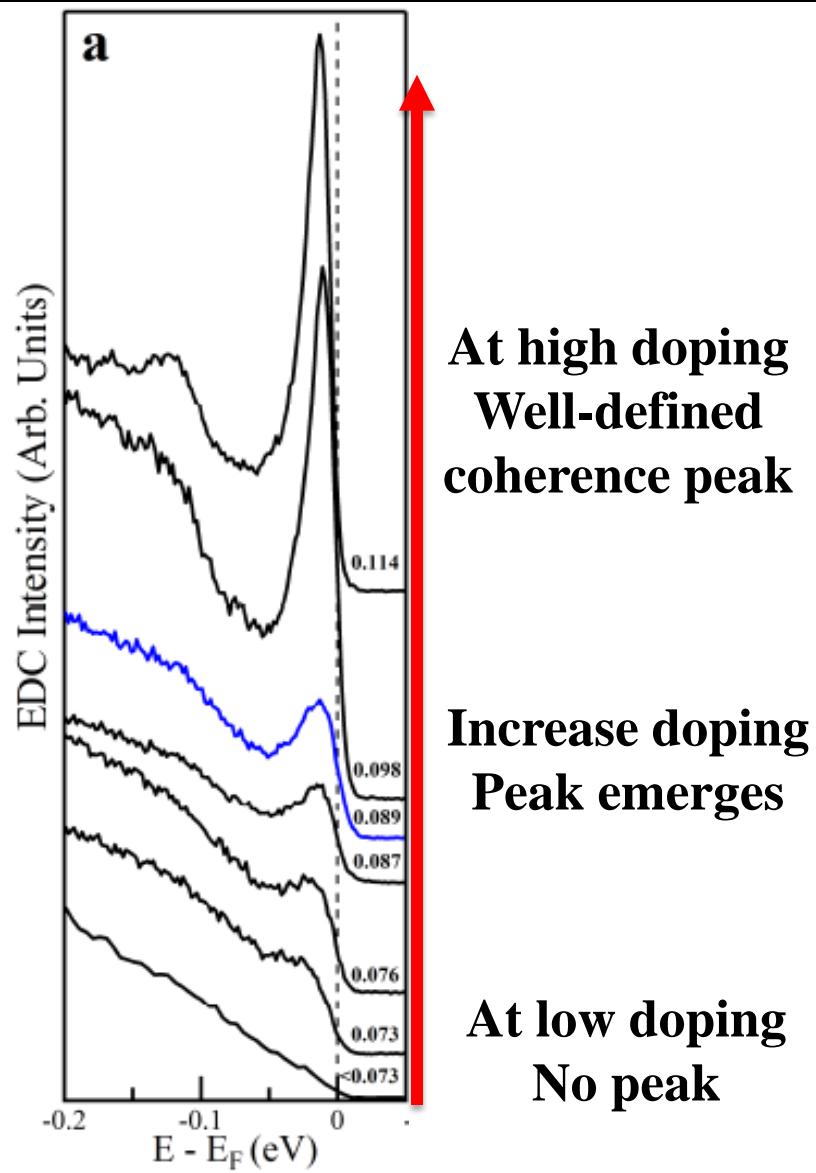
S. L. He, X. J. Zhou et al., Nature Materials 12, 605 (2013).

Band Structure Evolution of S Phase with Doping



Spectral weight increases with increasing electron doping.

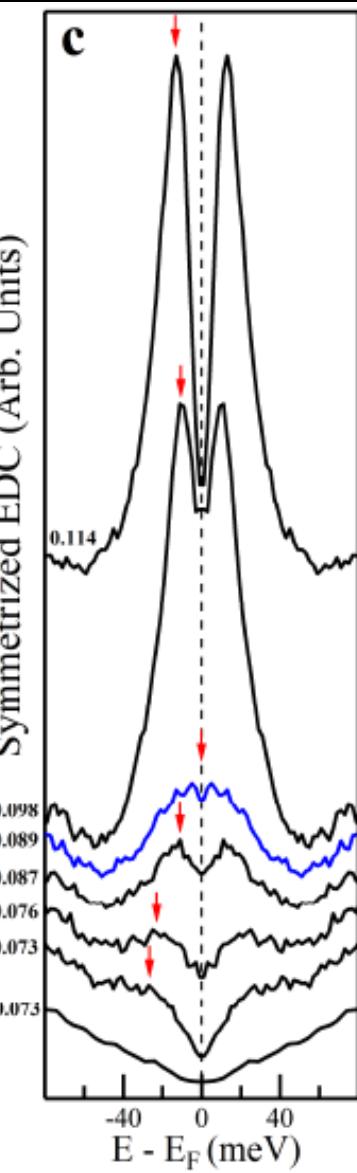
Doping Evolution of EDCs and Energy Gaps in S phase



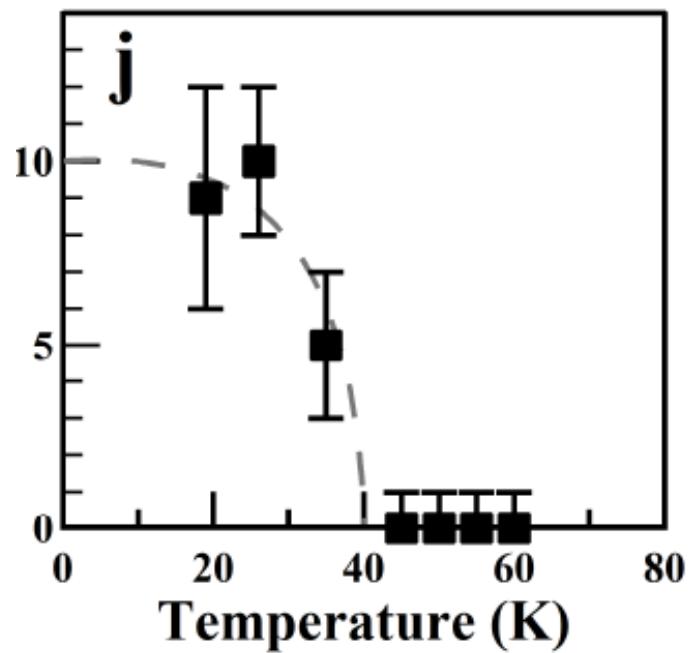
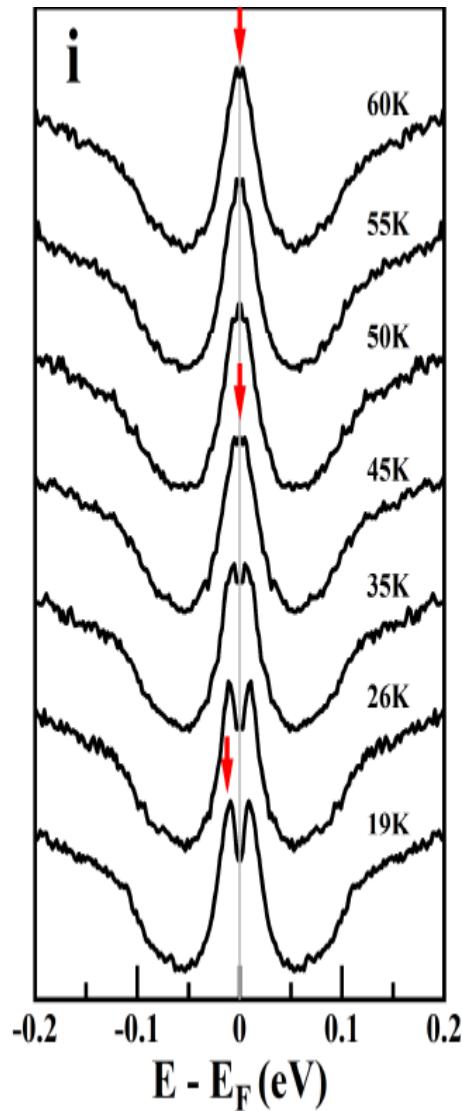
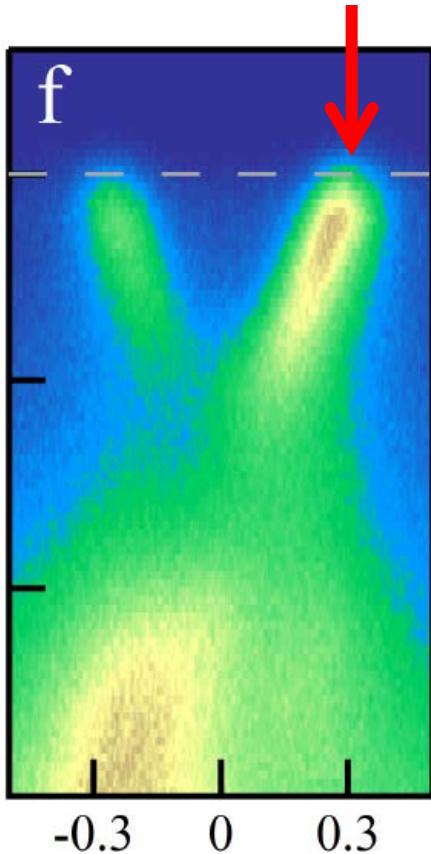
At high doping
Gap opens again
High-Doping Gap

Increase doping
Gap gets smaller and closes at doping 0.089

At low doping
Large gap opening
Low-Doping Gap



Temperature Dependence of High-Doping Gap



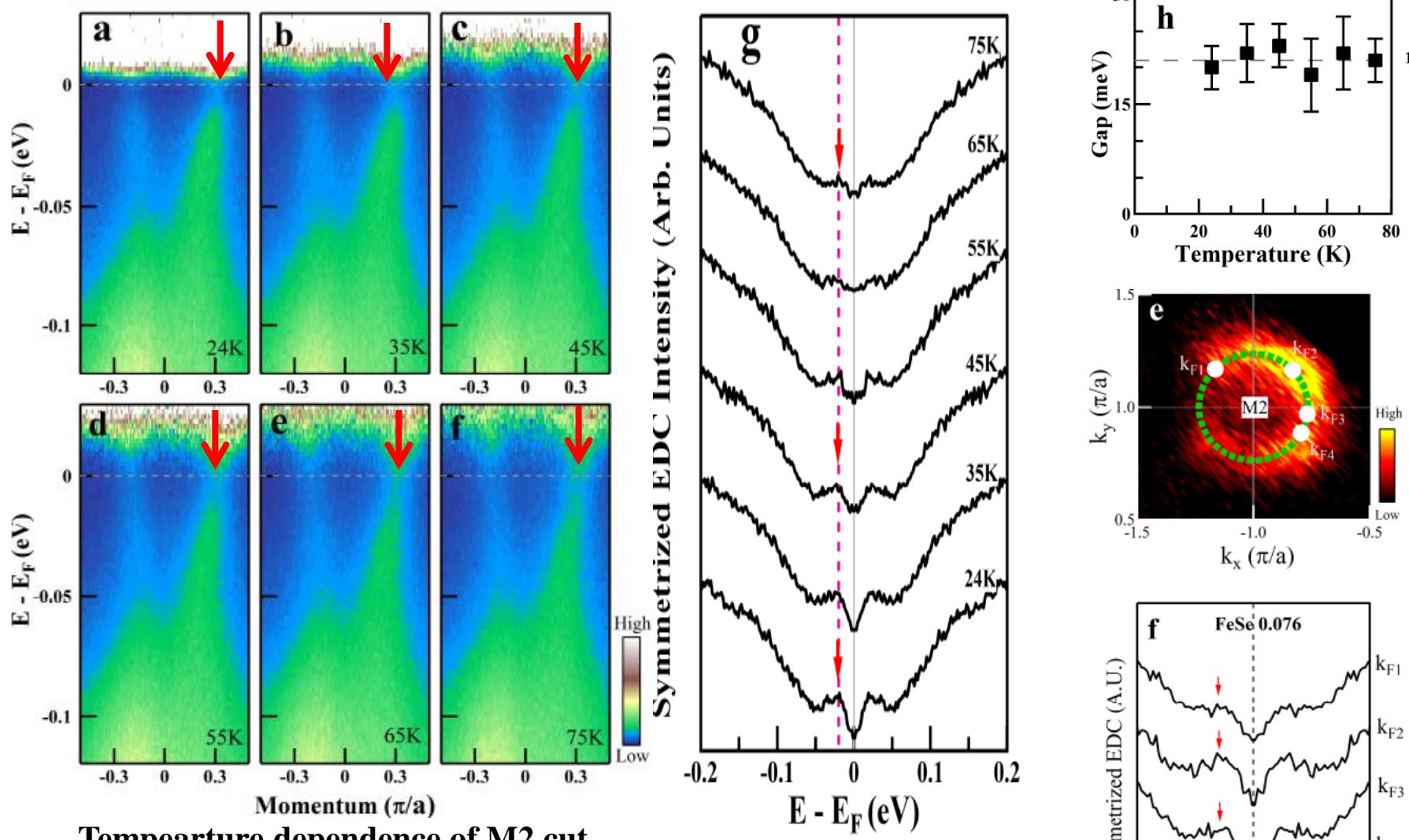
Well defined coherent peaks

Gap close around 45K,

Gap size follows BCS form

High-doping gap is a superconducting gap

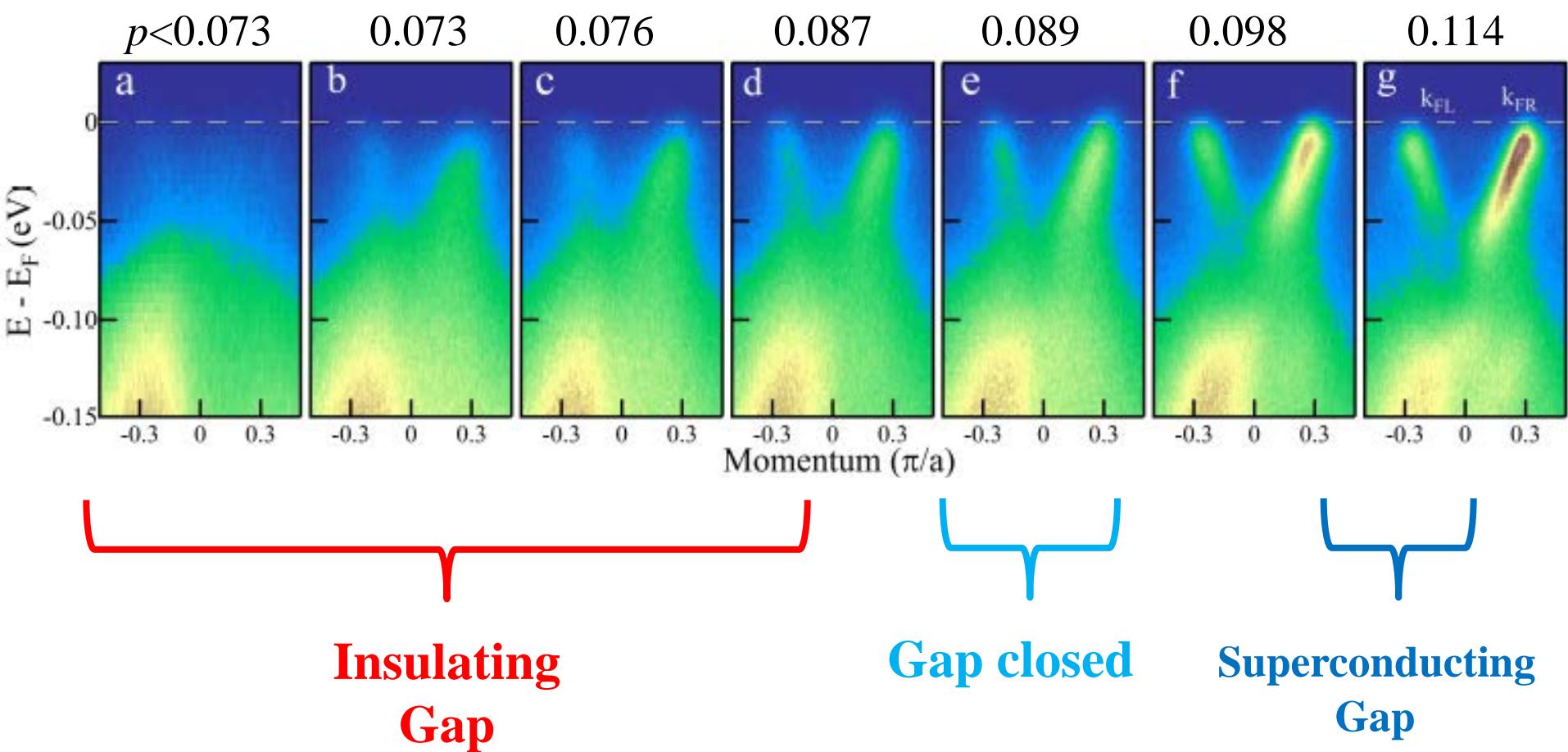
Temperature and Momentum Dependence of Low-Doping Gap



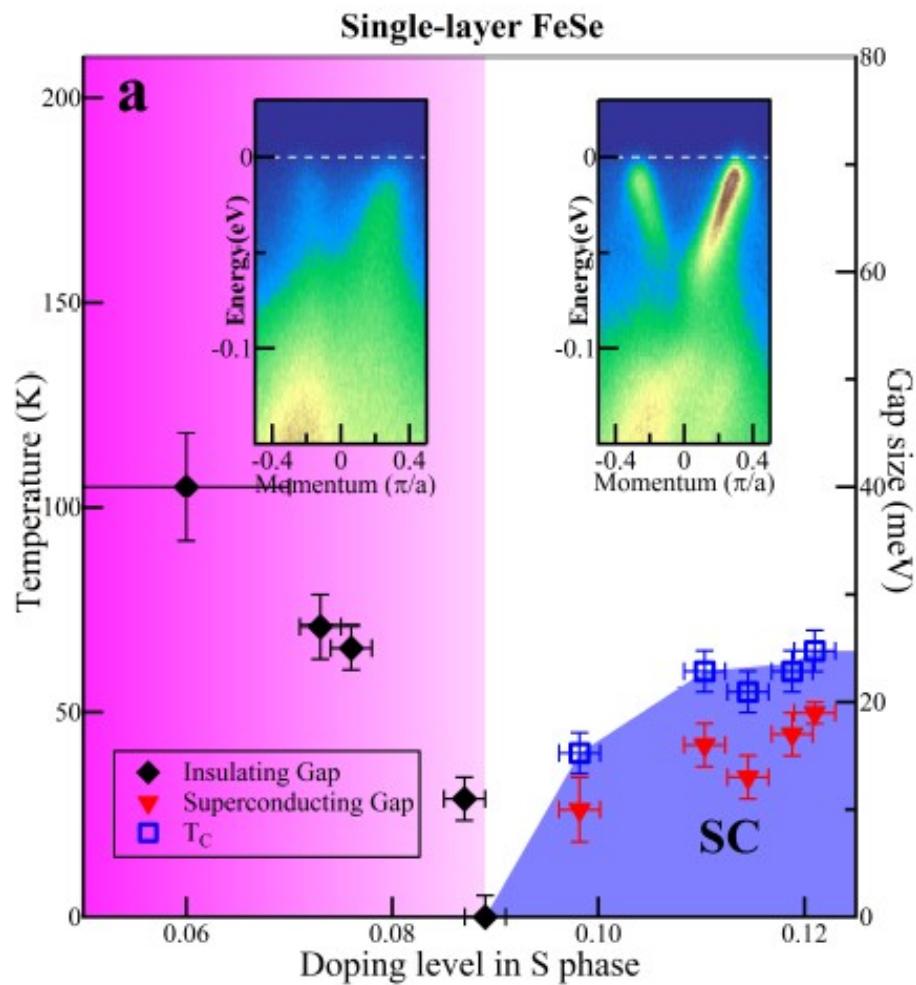
Tempearture dependence of M2 cut

Broad peak, Weak Temperature dependence of the Gap
→ insulating gap

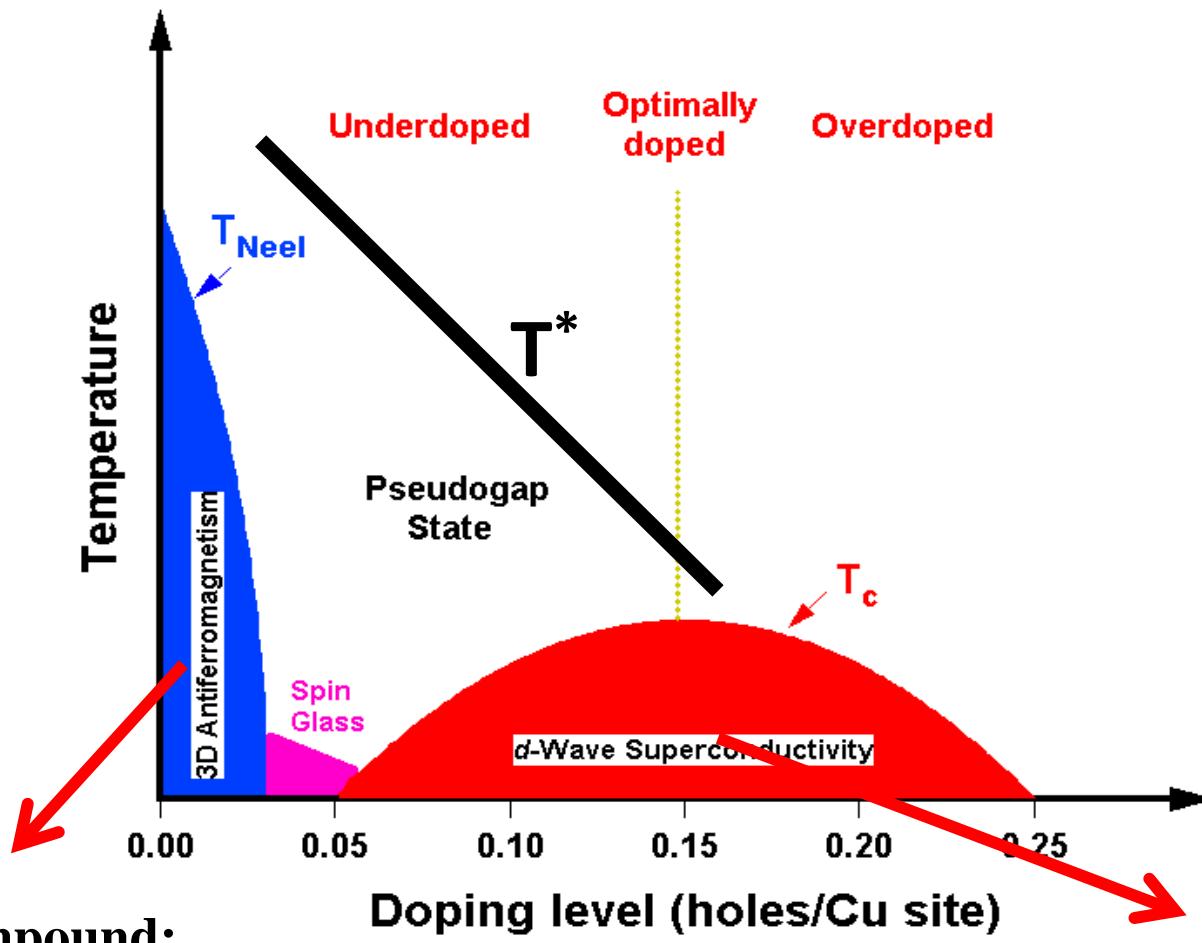
Insulator-Superconductor Transition in S-Phase of Single-Layer FeSe/SrTiO₃



Phase Diagram of S-Phase of Single-Layer FeSe/SrTiO₃



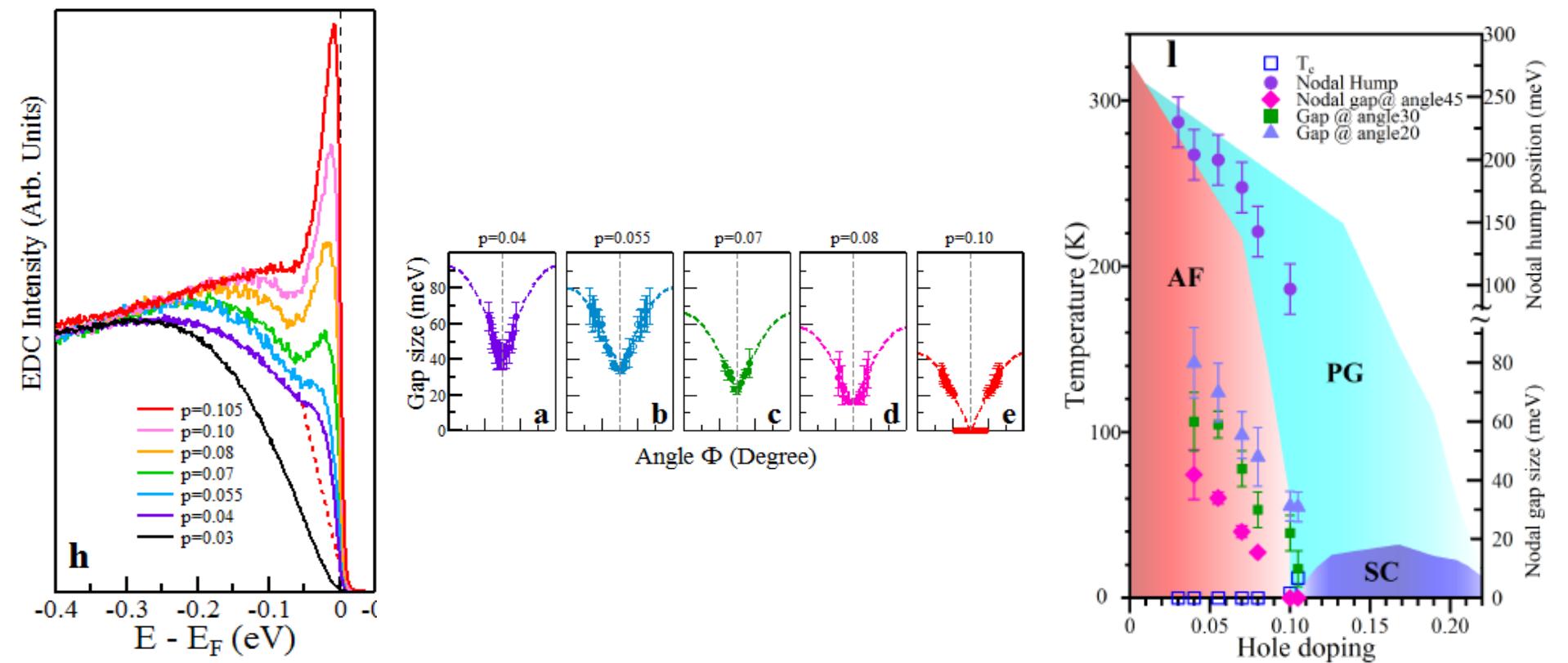
High-T_c Cuprate Superconductors: Doped Mott Insulator



Parent compound:
AFM Mott insulator

d-wave superconductor

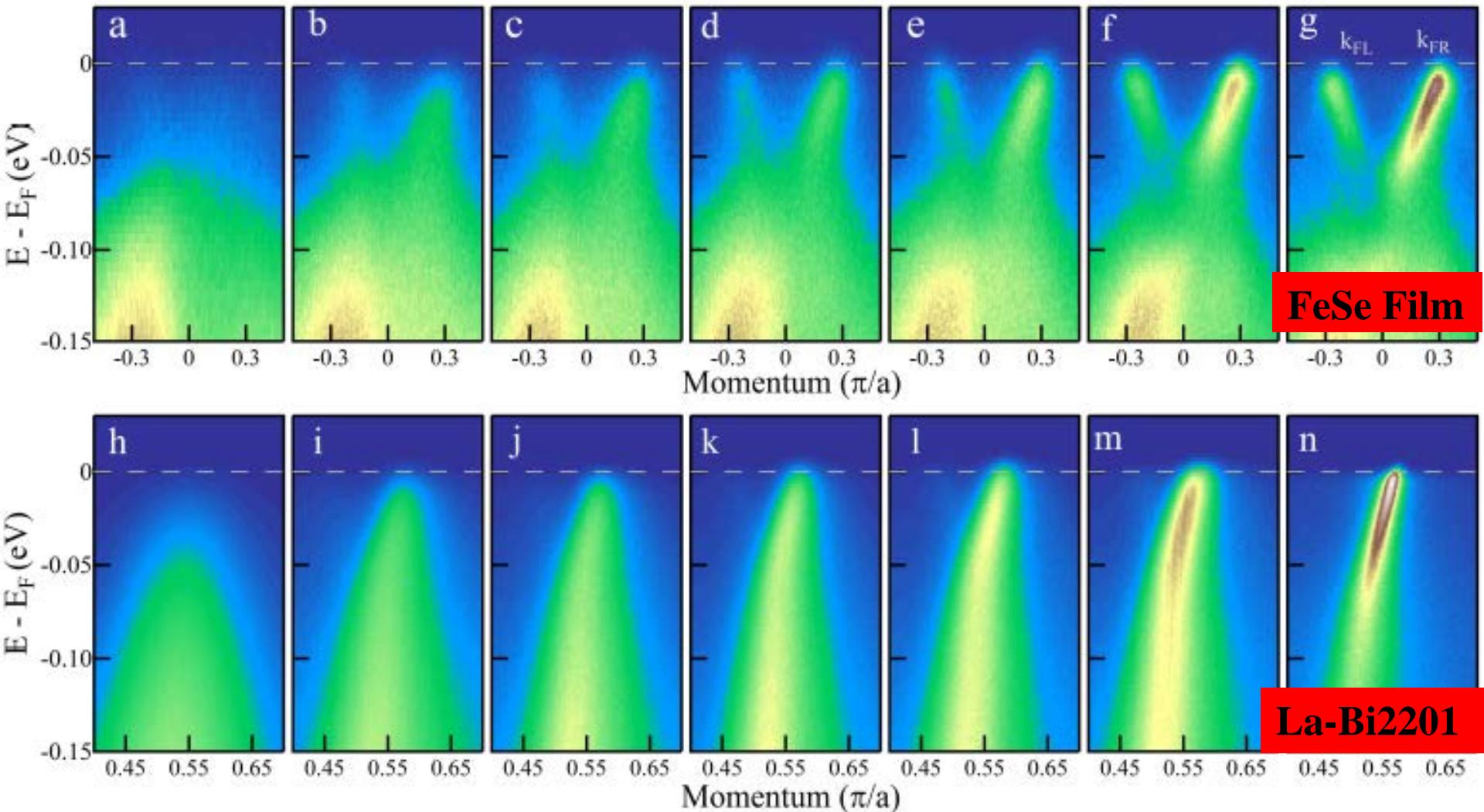
Insulator-Superconductor Transition in La-Bi2201



- Nodal gap forms below $p \sim 0.10$;
- Nodal gap decreases with increasing doping and vanishes at $p \sim 0.10$;
- Near $p \sim 0.10$, (1). The 3D antiferromagnetic order disappears;
(2). Superconductivity starts to emerge;
(3). Nodal gap gets to zero.

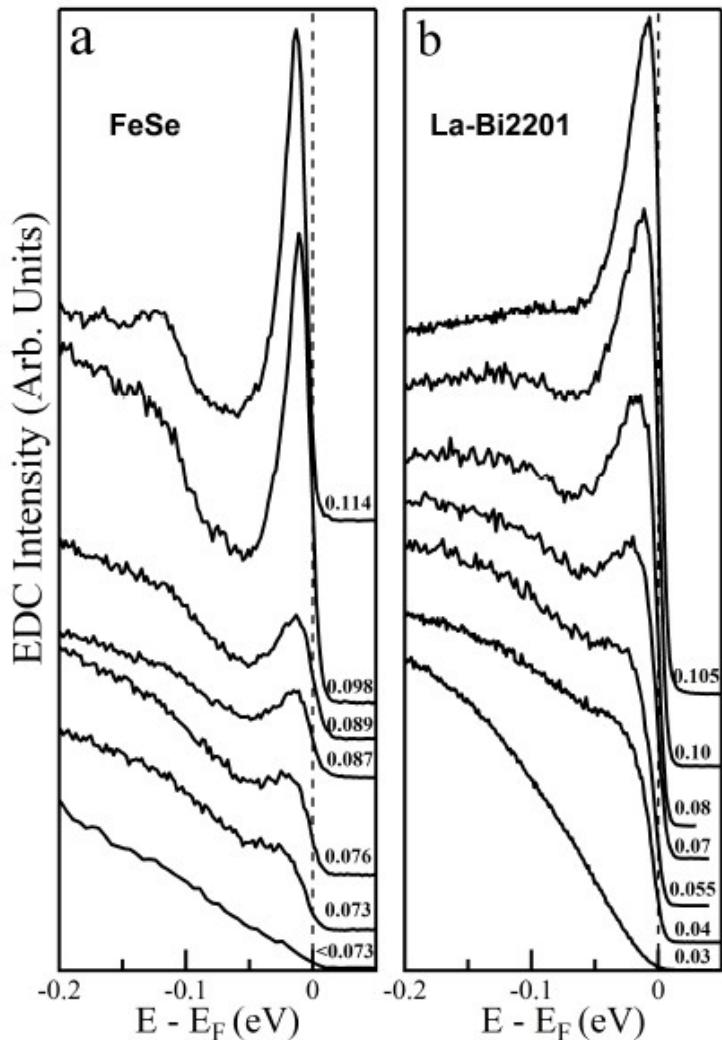
Similarity between Single-Layer FeSe Film and La-Bi2201

1. Band Structure Evolution

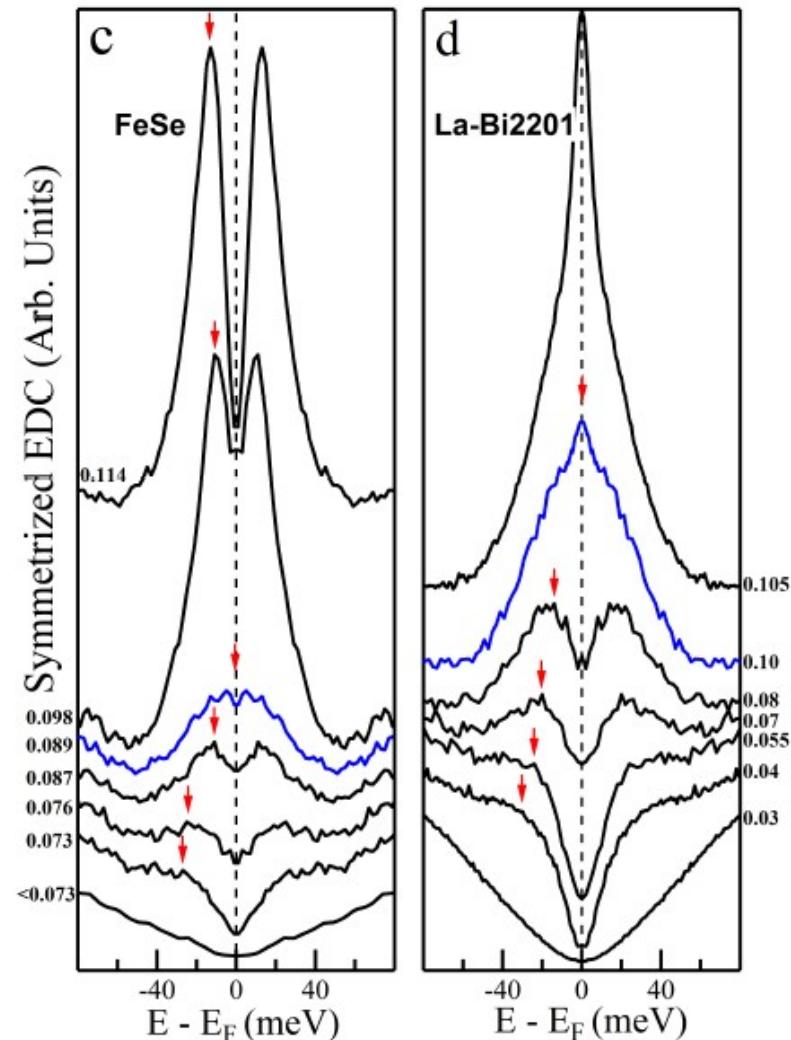


Similarity between Single-Layer FeSe Film and La-Bi2201

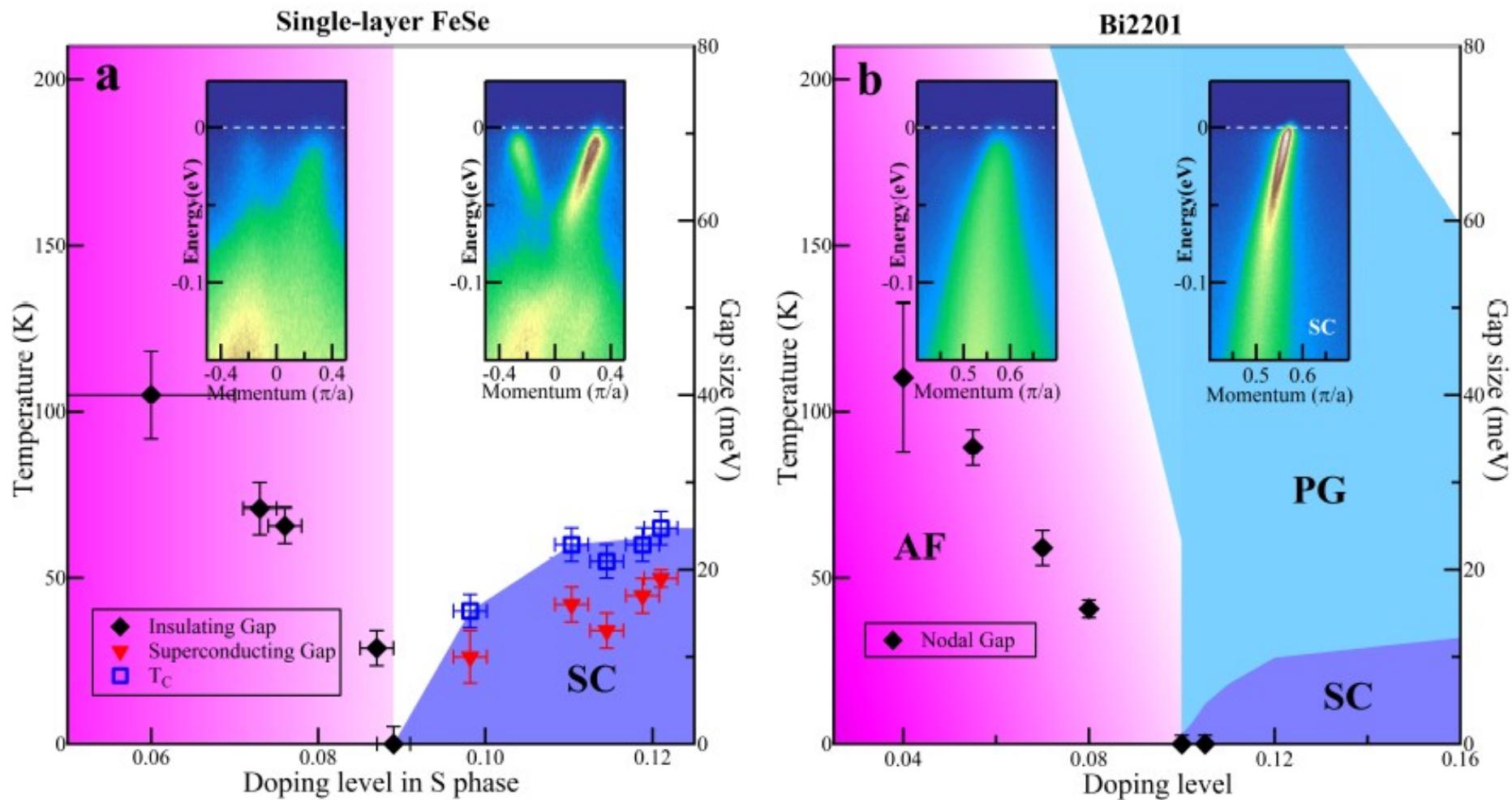
2. EDC Cohenerce Peak Evolution



3. Insulating Gap Evolution

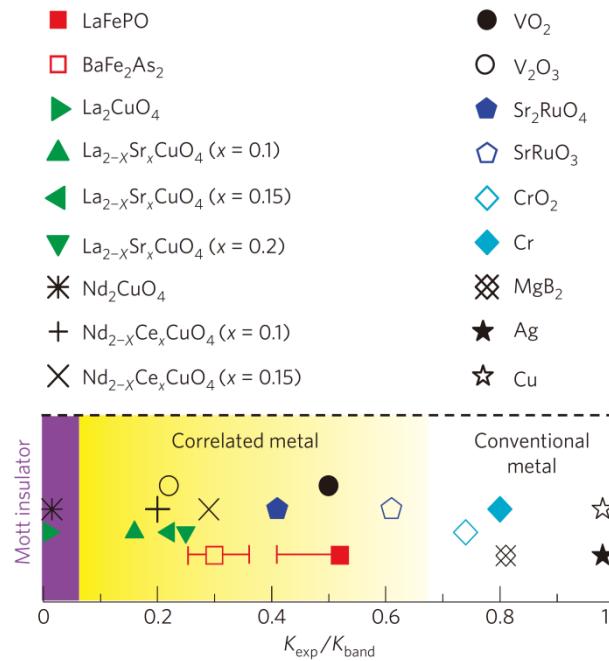


Similar Electronic Phase Diagrams



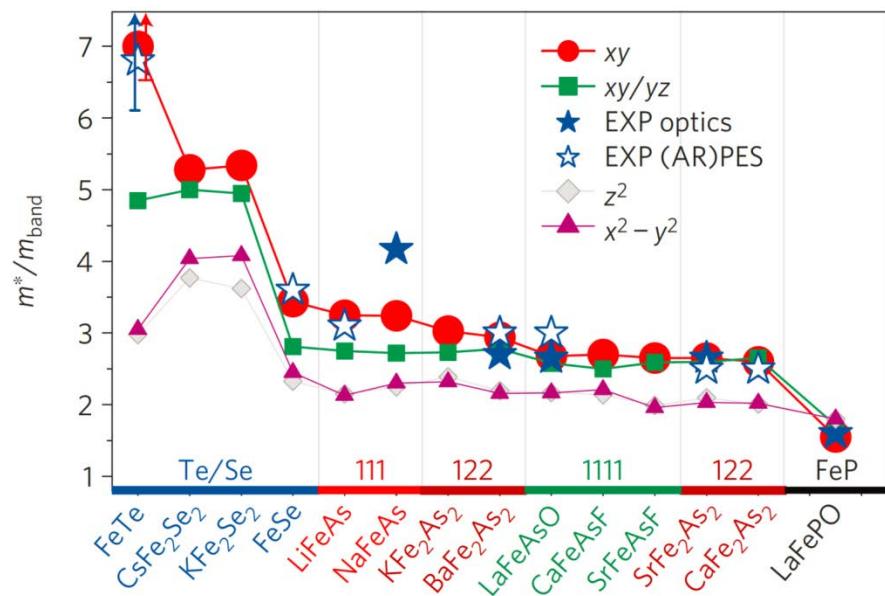
Strong Correlation in Single-Layer FeSe/SrTiO₃ Film

1. Existence of Electron Correlation in Fe-based Compounds



M. M. Qazibash et al., Nature Phys. 5, 647 (2009)

2. Stronger Electron Correlation in 11-Based Compounds

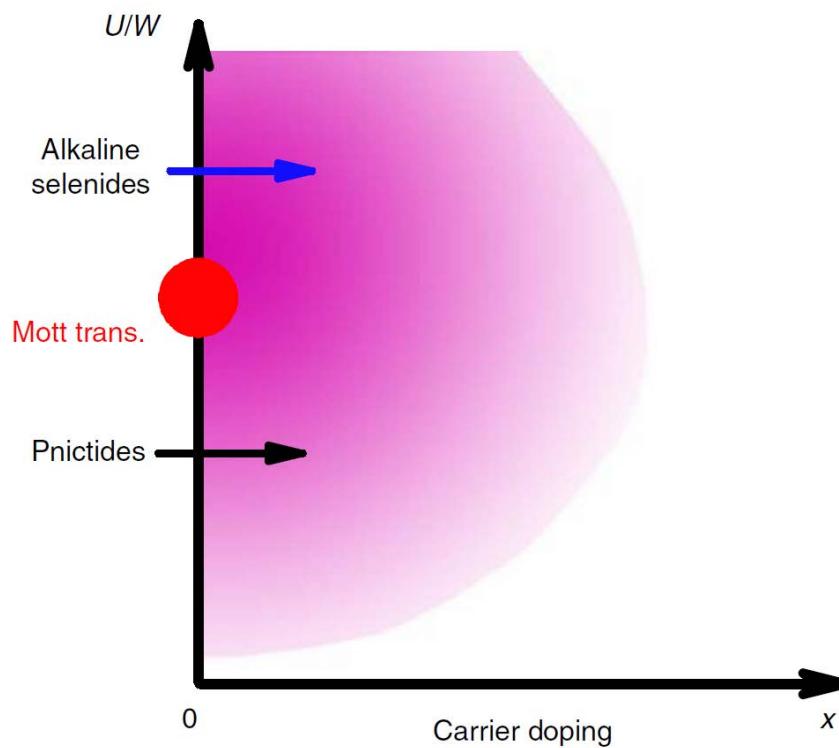


Z. P. Yin et al., Nature Mater. 10, 932 (2011).

3. Enhanced electron correlation due to reduced dimensionality—2D film;
4. Enhanced electron correlation due to tensile strain in single-layer FeSe film
(Bulk FeSe: 3.76 Å, Single-layer FeSe/SrTiO₃ film: 3.80 Å)

Doping of the Orbital-Selective Mott Insulator?

- Fe-based compounds are on the verge of doped Mott insulator;
- Single-Layer FeSe/SrTiO₃ has particularly strong electron correlation.
- Similarity between Single-layer FeSe/SrTiO₃ Film and the underdoped La-Bi2201.

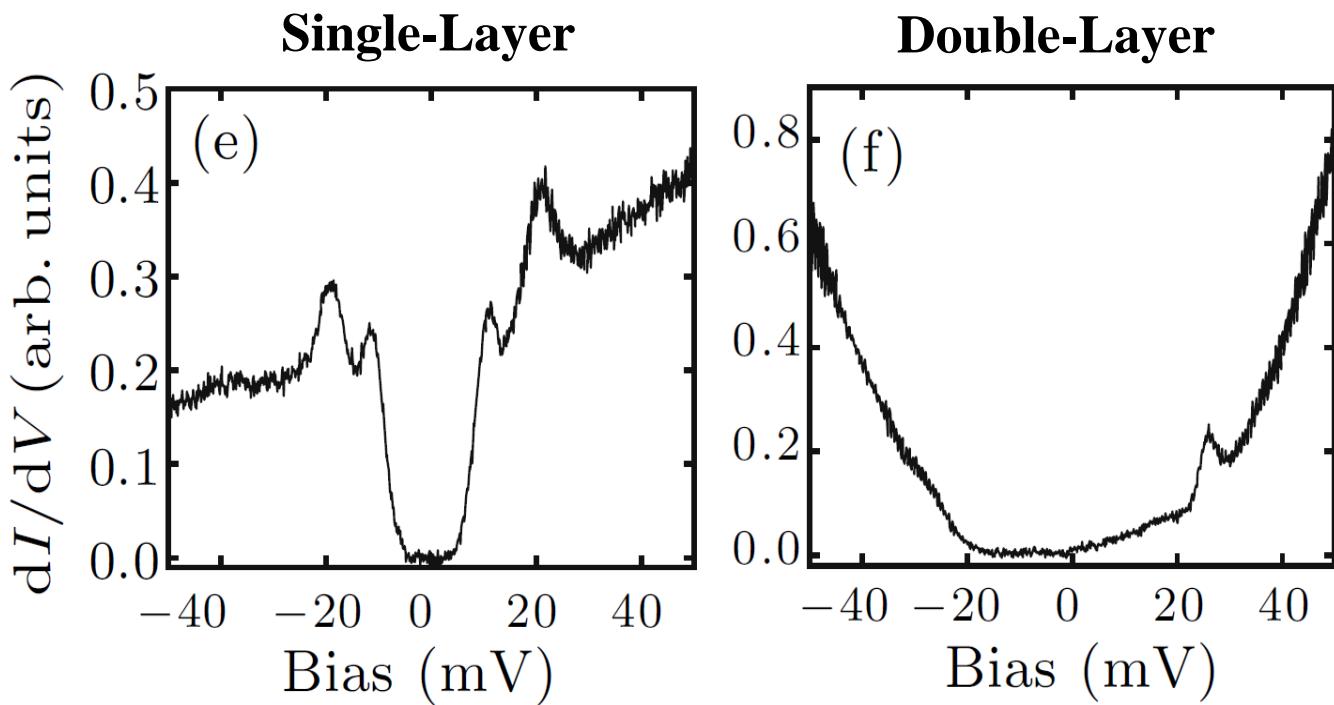
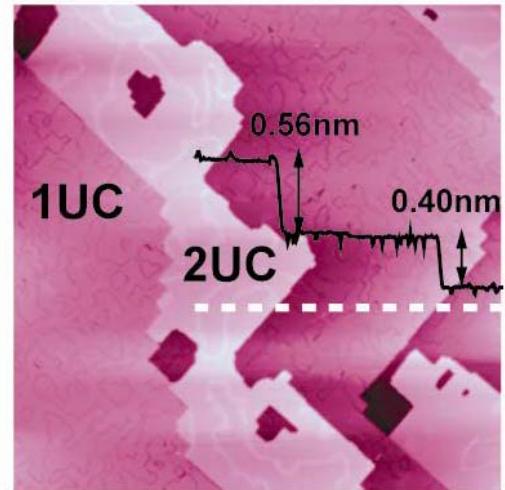


- Q. M. Si and E. Abrahams, Phys. Rev. Lett. 101, 076401 (2008).
R. Yu et al., Nature Communications 4, 2783 (2013).
R. Yu and Q. M. Si, Phys. Rev. Lett. 110, 146402 (2013).

Dichotomy of Electronic Structure and Superconductivity between the Single-Layer and Double-Layer FeSe/SrTiO₃

X. Liu, D. F. Liu, W. H. Zhang, J. F. He, X. C. Ma, Q. K. Xue, X. J. Zhou et al.,
Nature Communications 5, 5047(2014).

Distinct Behaviors between Single-Layer and Two-Layer FeSe/SrTiO₃: STM/STS

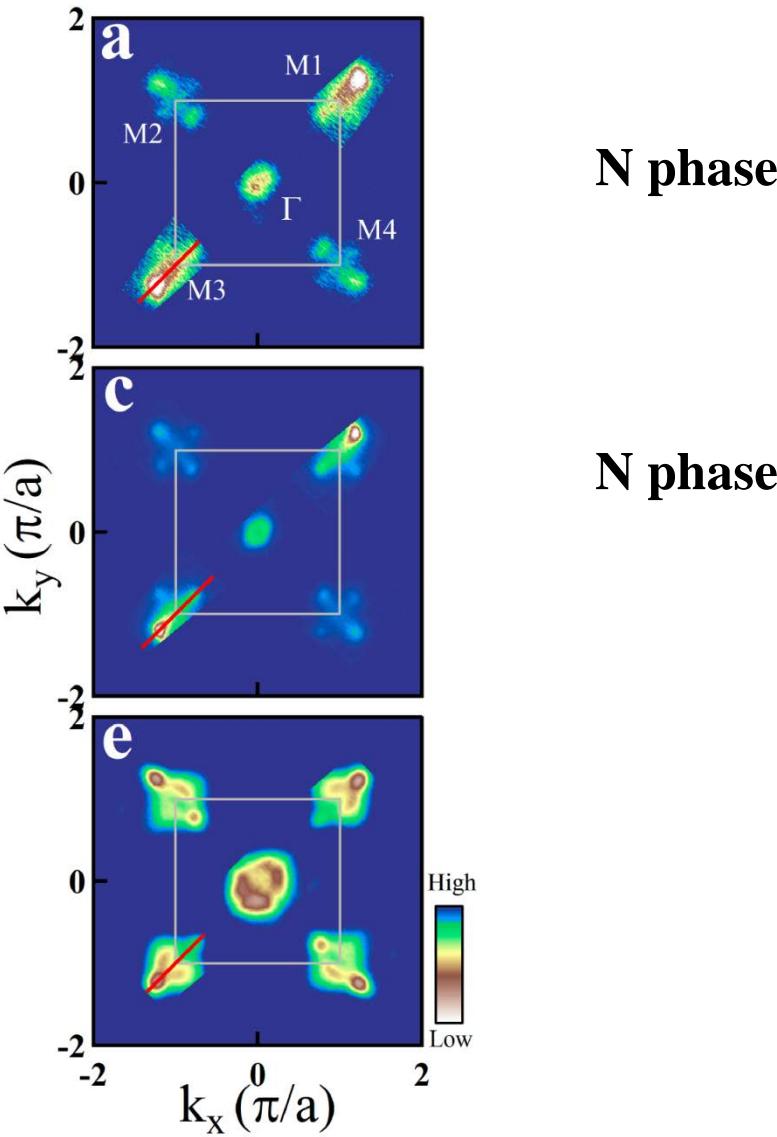


As-prepared single-layer and double-layer FeSe/SrTiO₃ are in N phase

Single-Layer
FeSe/SrTiO₃

Double-Layer
FeSe/SrTiO₃

BaFe₂As₂



N phase

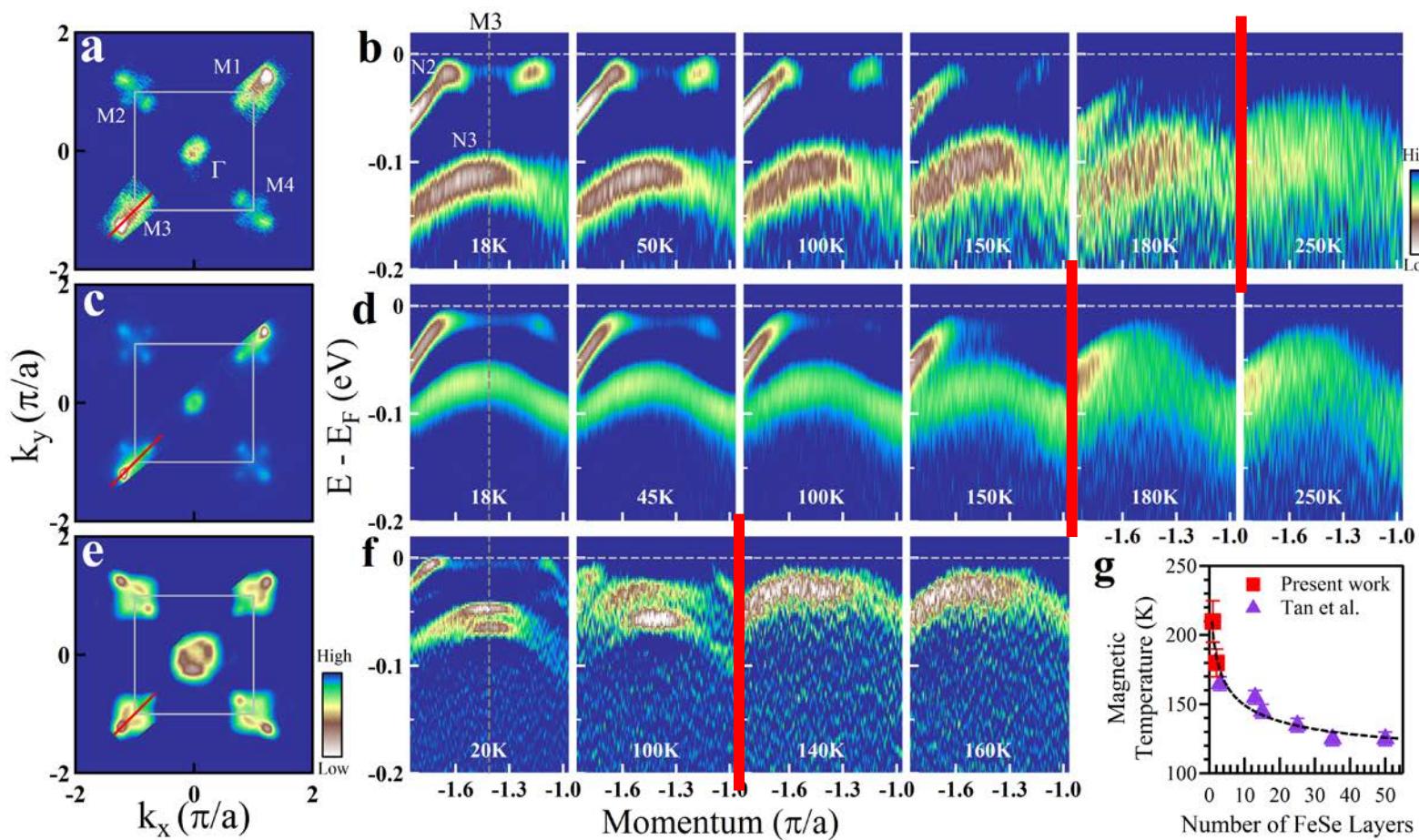
N phase

The Fermi surface, M point band and its temperature dependence resemble those in BaFe_2As_2 below the magnetic/structural transition

Single-Layer
 FeSe/SrTiO_3

Double-Layer
 FeSe/SrTiO_3

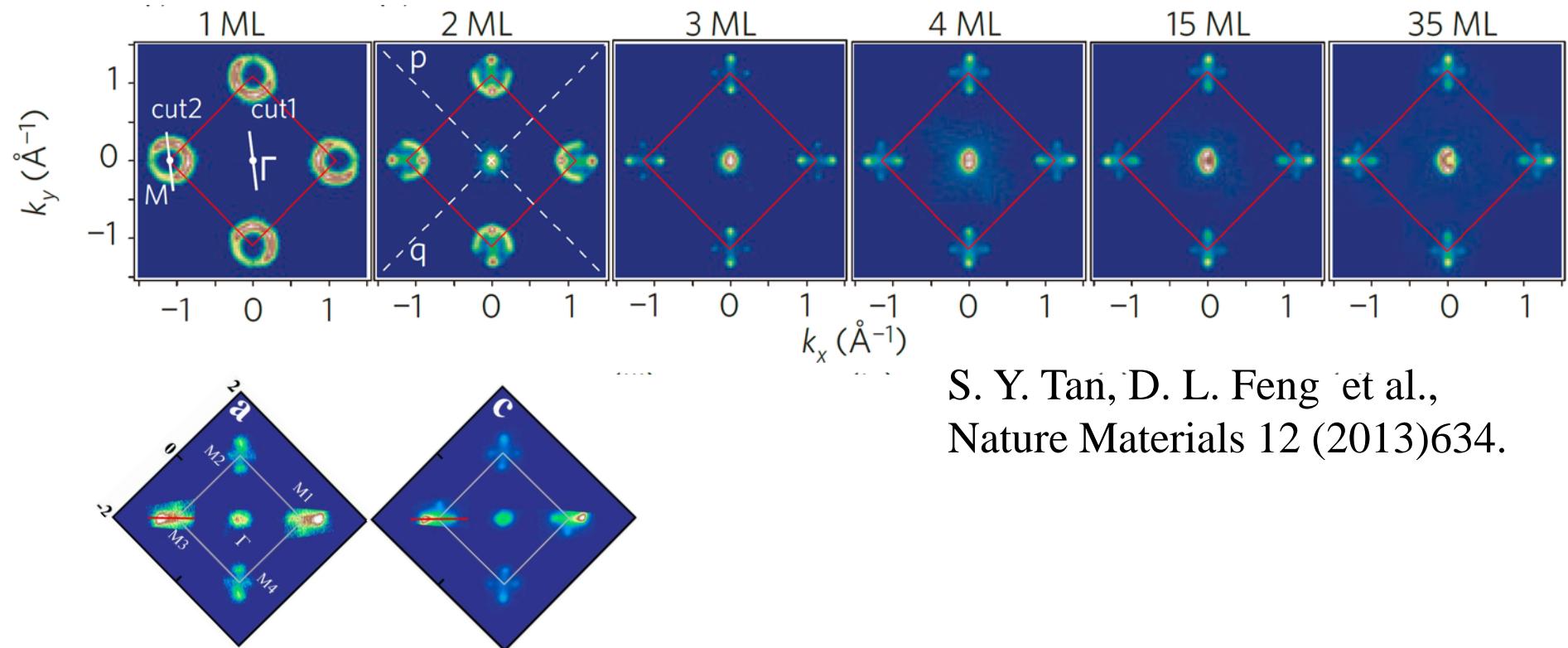
BaFe_2As_2
($T_{N,S}=138\text{K}$)



The N Phase in as-prepared FeSe/SrTiO_3 is likely magnetic.
Further direct measurement is needed.

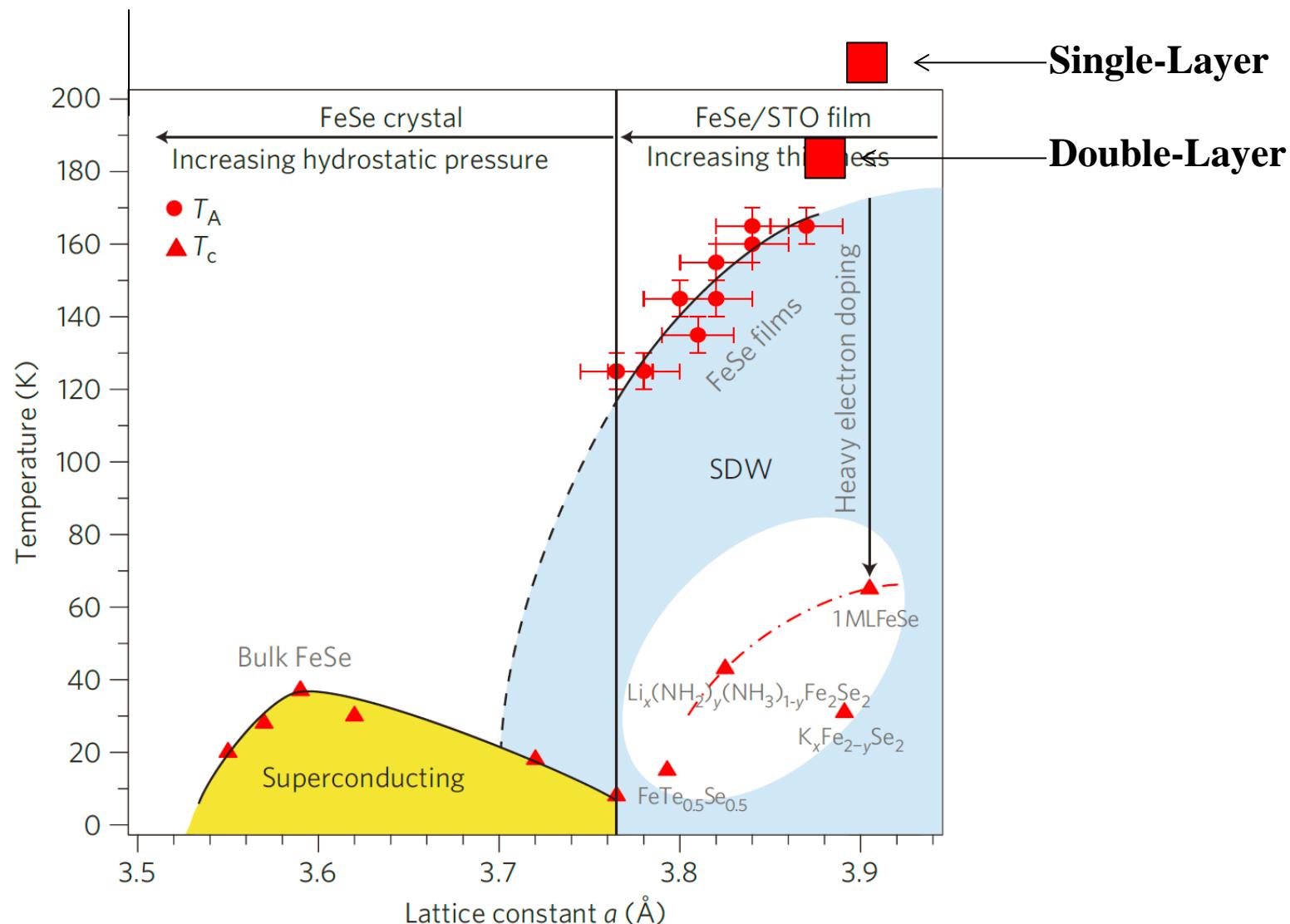
X. Liu, X. J. Zhou et al., Nature Communications 5, 5047(2014).

N Phase is Present in Single-Layer and Double-Layer FeSe/SrTiO₃



X. Liu, X. J. Zhou et al.,
Nature Communications 5, 5047(2014).

Transition Temperature vs Number of FeSe Layers



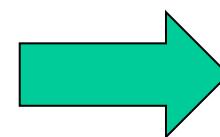
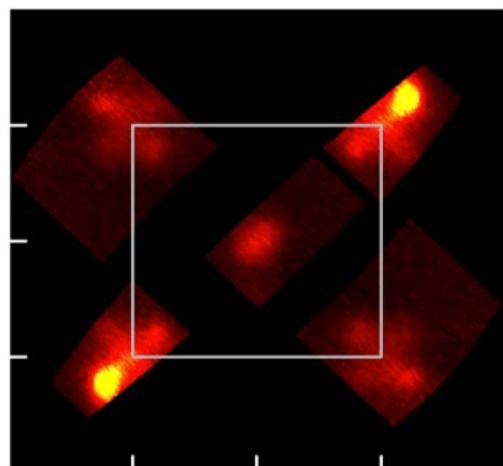
S. Y. Tan, D. L. Feng et al., Nature Materials 12 (2013) 634;
X. Liu, X. J. Zhou et al., Nature Communications 5, 5047(2014).

Distinct Behaviors between Single-Layer and Double-Layer FeSe/SrTiO₃

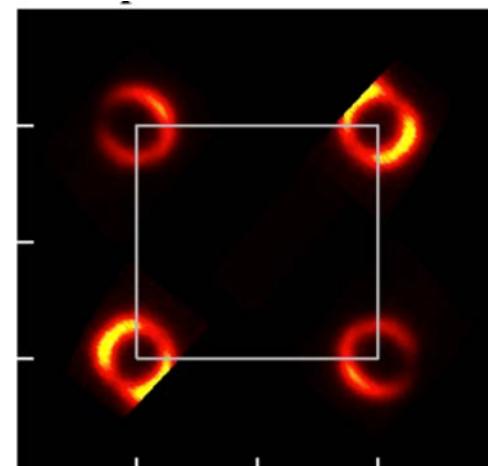
Vacuum Annealed under *Same* Conditions

Single-Layer
FeSe/STO

N

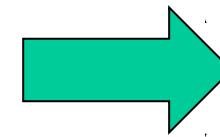
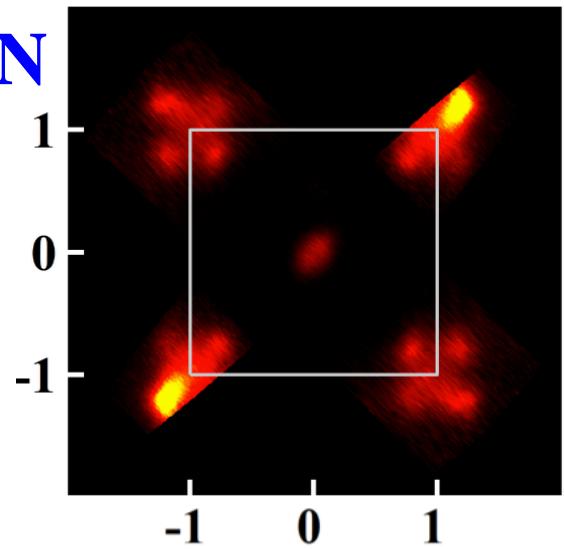


S

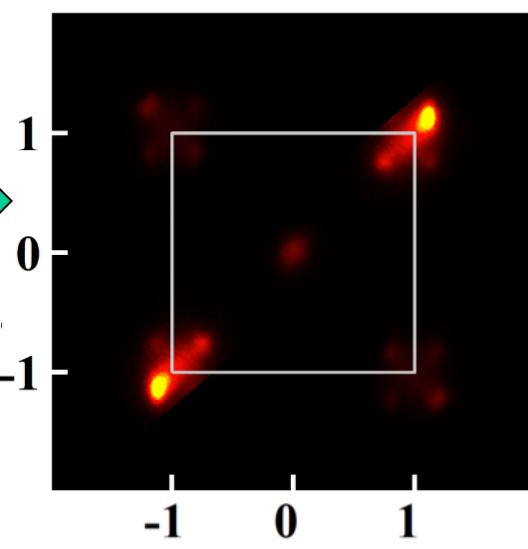


Double-Layer
FeSe/STO

N



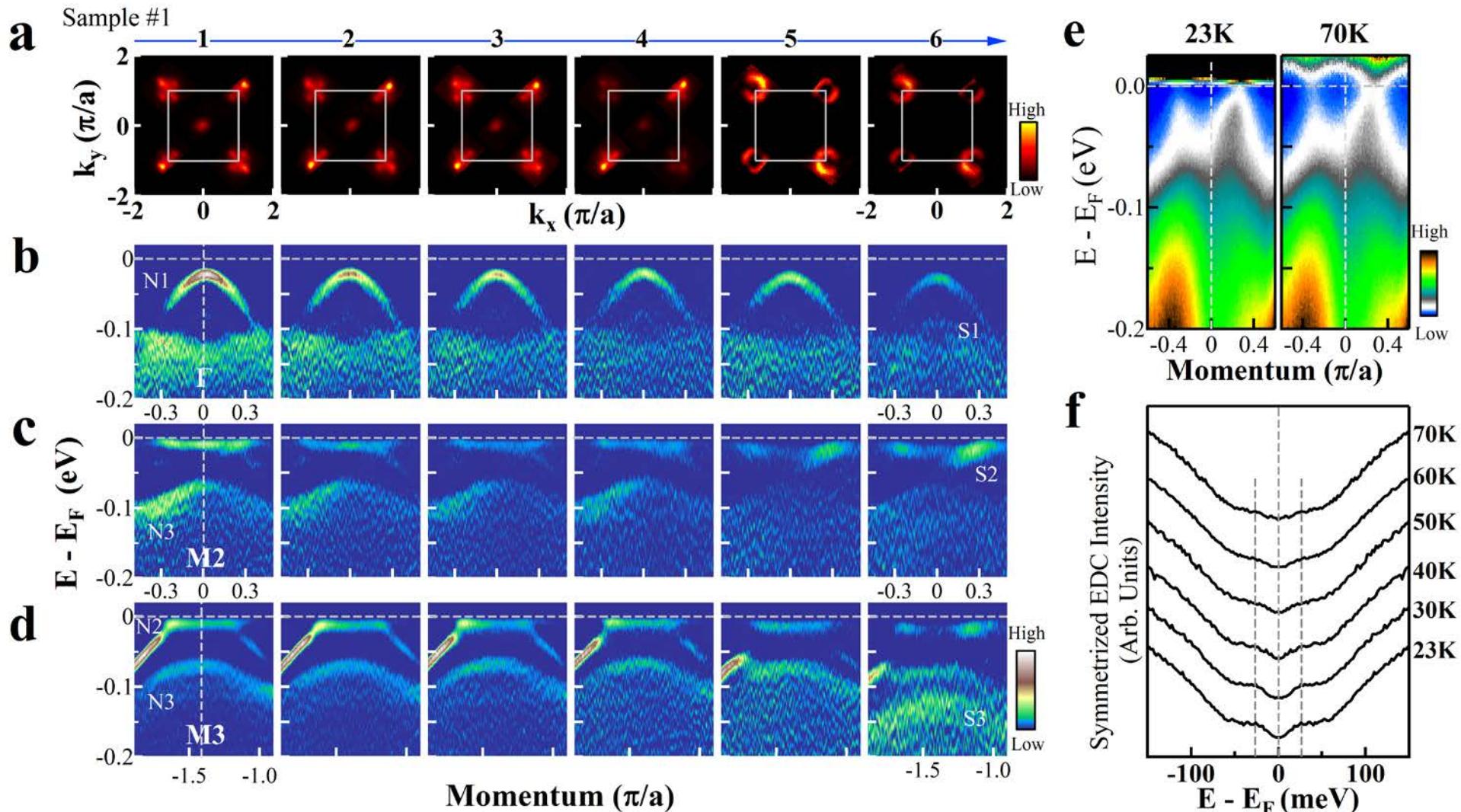
N



**Let us now enhance the vacuum-annealing condition
for the double-layer FeSe/SrTiO₃**

Way 1:

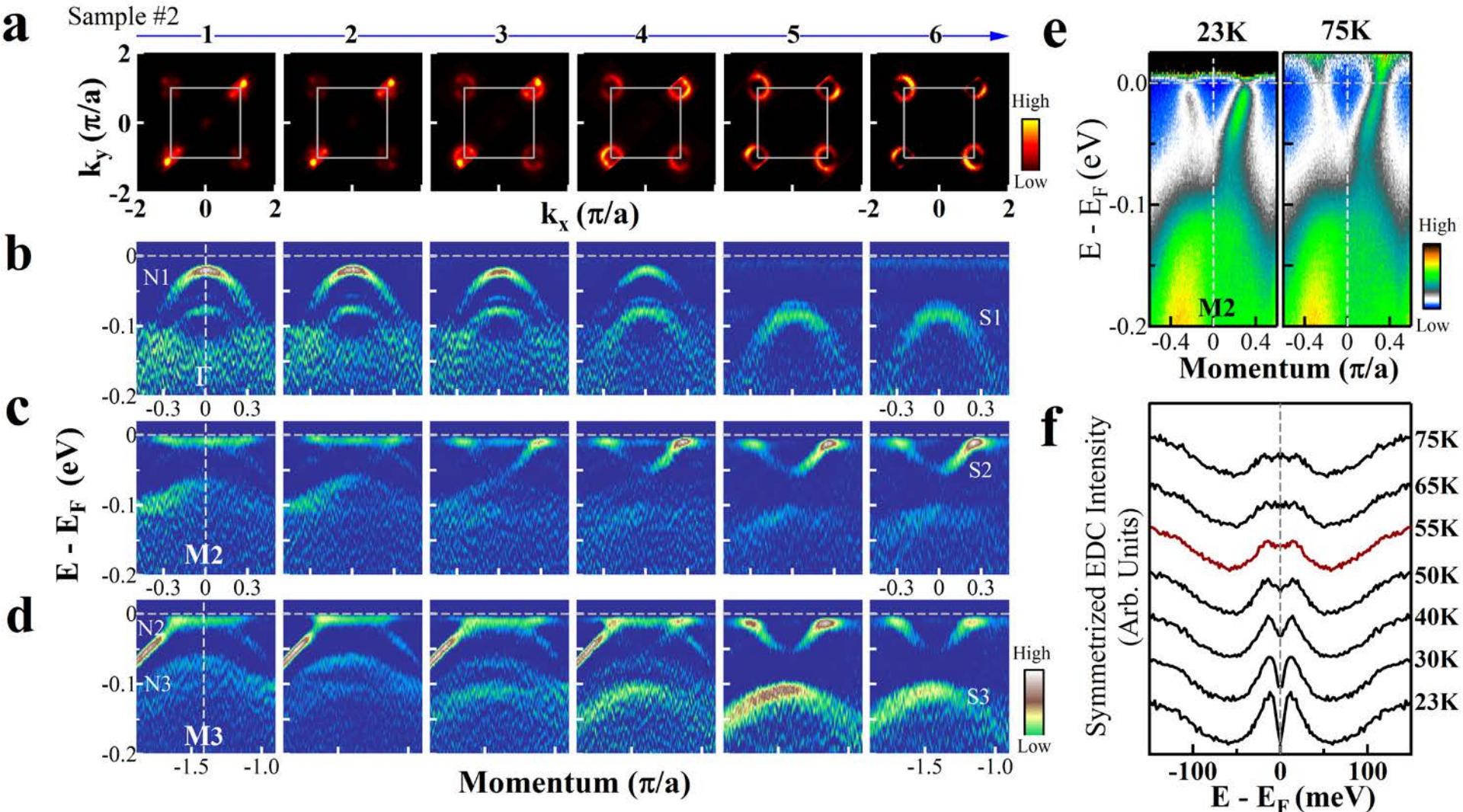
Vacuum Annealing of Double-Layer FeSe/SrTiO₃ at 350C for different Times



1. The N phase remains dominant after annealing;
2. There is a transition from the N phase to the S phase.

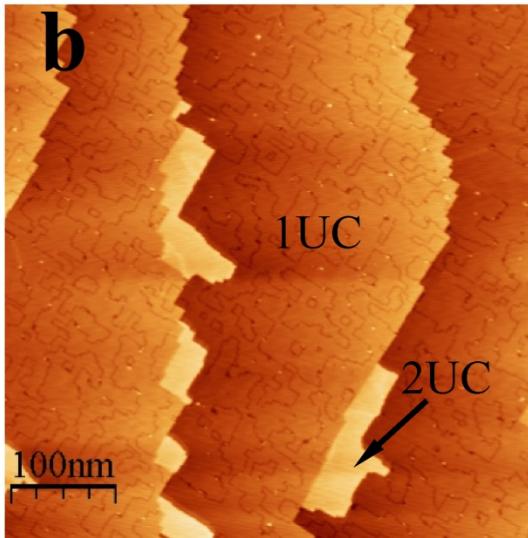
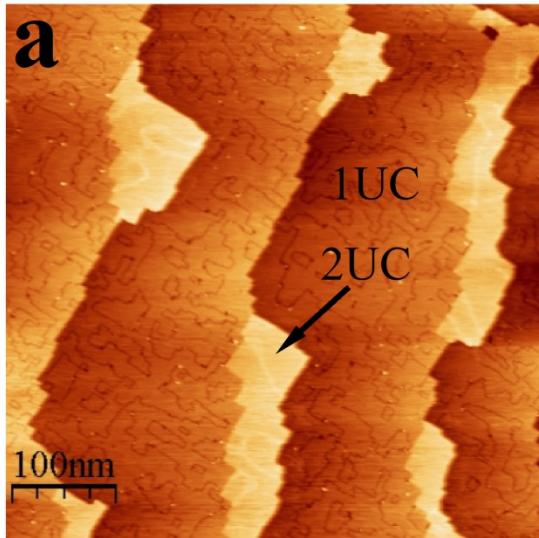
Way 2:

Vacuum Annealing of Double-Layer FeSe/SrTiO₃ at Increasing Temperature



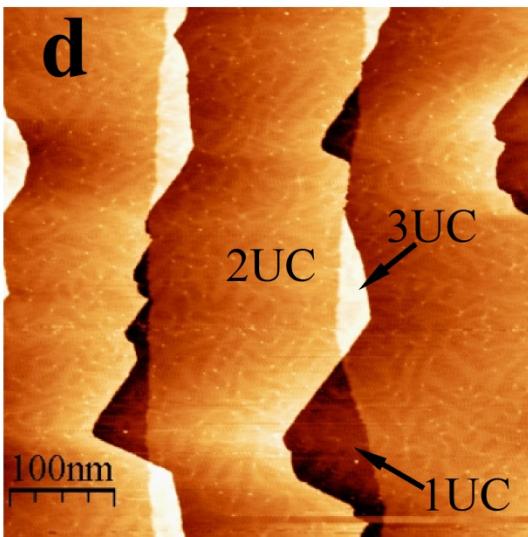
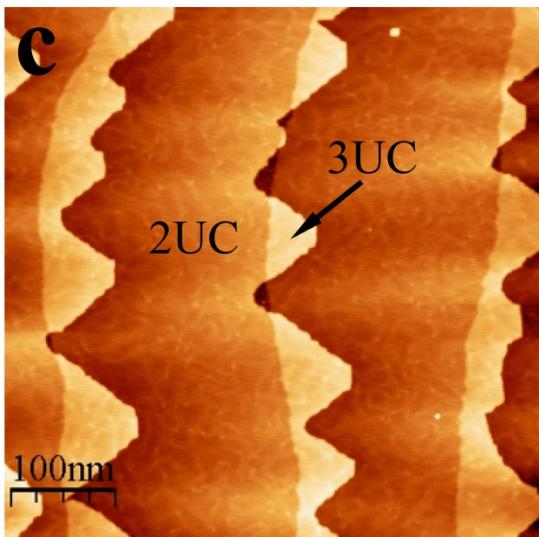
1. The N Phase transforms completely into pure S phase;
2. It becomes superconducting.

STM Observations During Annealing Process



STM images before (a) and after (b) the sample was annealed at 450 C for 15 hours.

No obvious FeSe evaporation

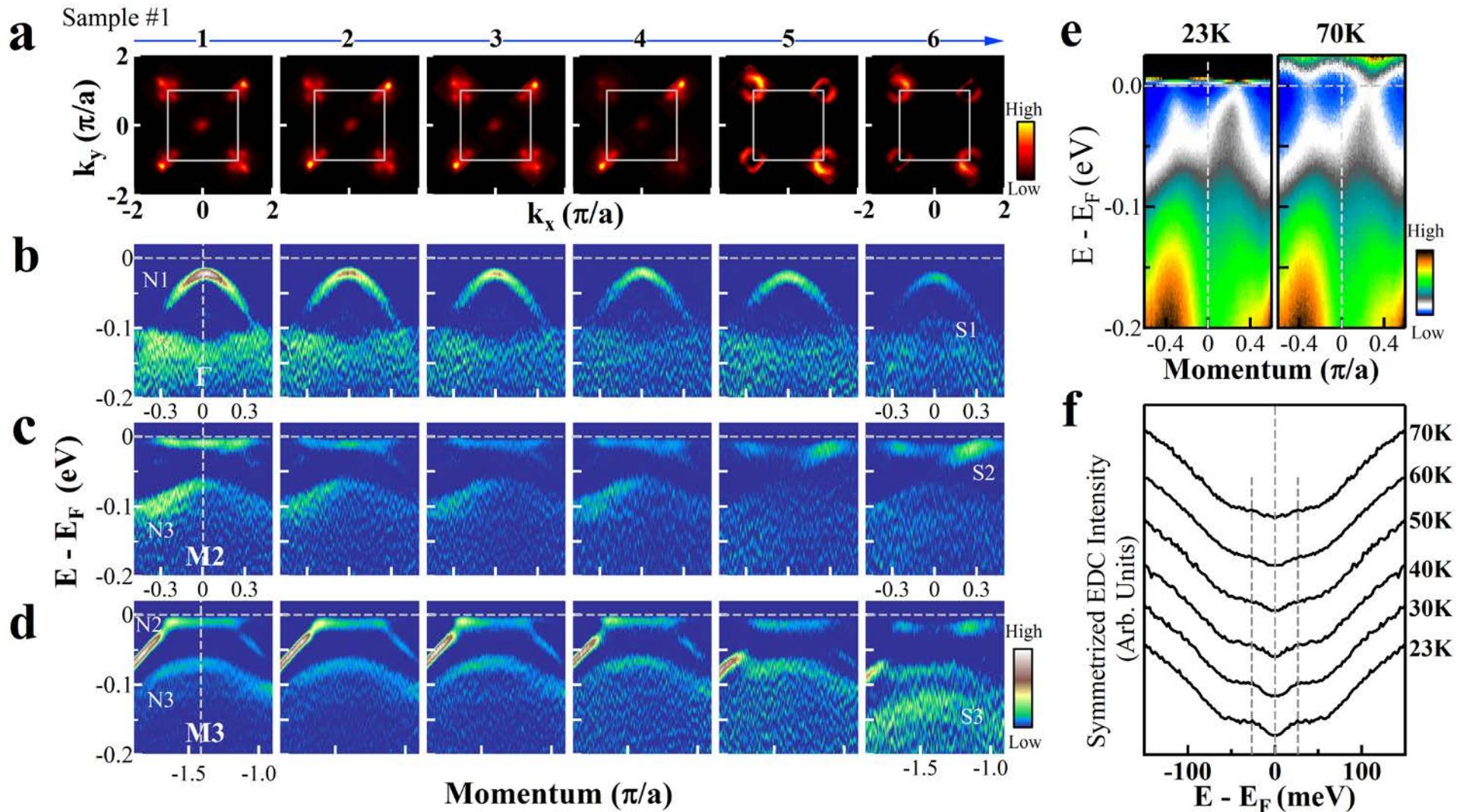


STM images before (c) and after (d) the sample was annealed at 500 C for 3 hours.

Obvious FeSe evaporation

Way 1:

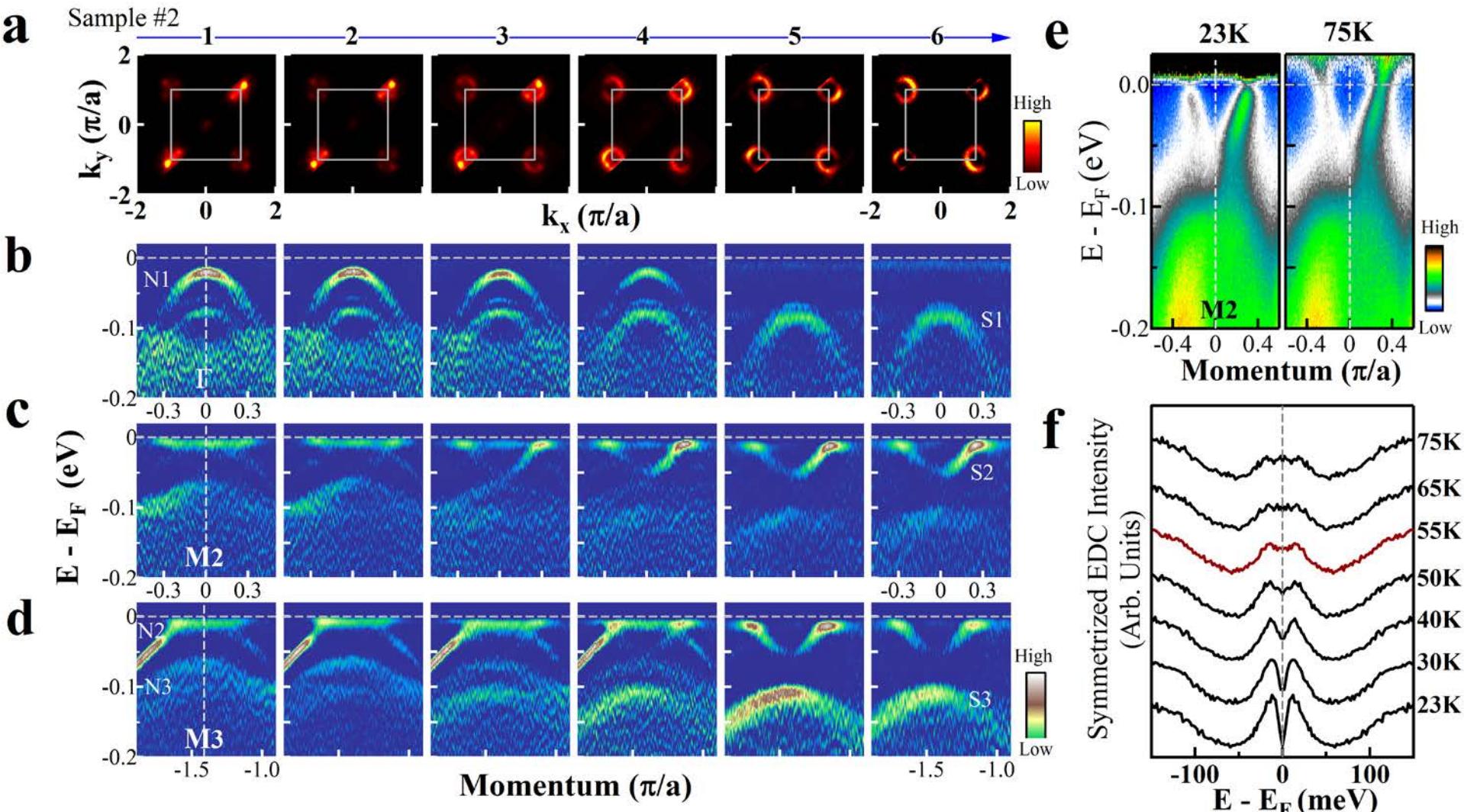
Vacuum Annealing of Double-Layer FeSe/SrTiO₃ at 350C for different Times



At 350C, the double-layer FeSe/SrTiO₃ film remains intact

Way 2:

Vacuum Annealing of Double-Layer FeSe/SrTiO₃ at Increasing Temperature



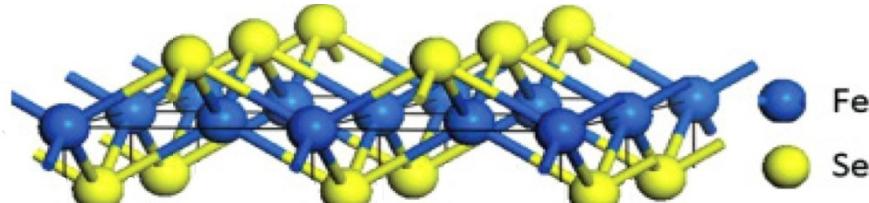
1. Most likely, two-layers may become evaporated into single-layer;
2. The superconductivity may be caused by exposed single-layer region.

- It is much harder to transform double-layer from the N phase into the S phase than the single-layer FeSe/SrTiO₃.
- It is possible to transform double-layer FeSe/SrTiO₃ from the N phase into the S phase.

Origin of Electron-Doping during Annealing

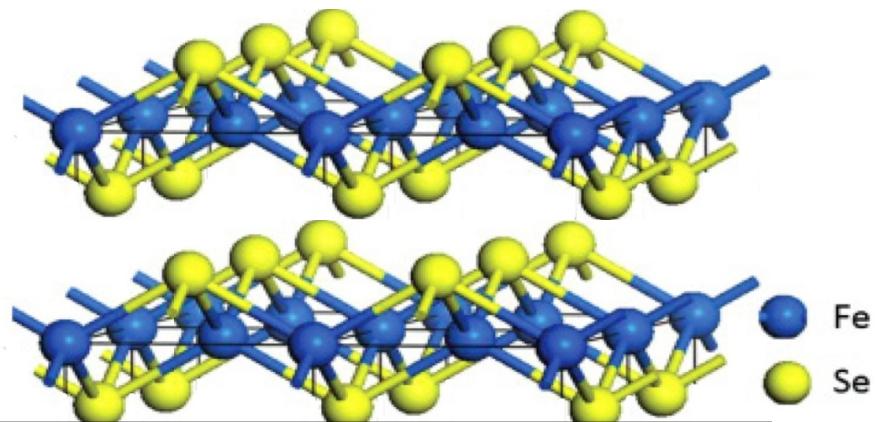
1. Excess Se removal or Se vacancy Formation in FeSe_{1-x} ?
Less likely
2. Charge transfer from oxygen loss in $\text{SrTiO}_{3-\delta}$? 

Single-Layer



SrTiO₃ Substrate

Double-Layer

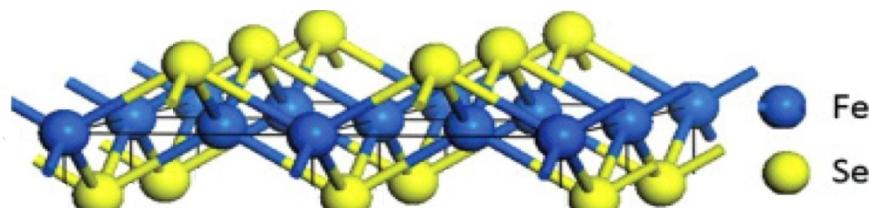


SrTiO₃ Substrate

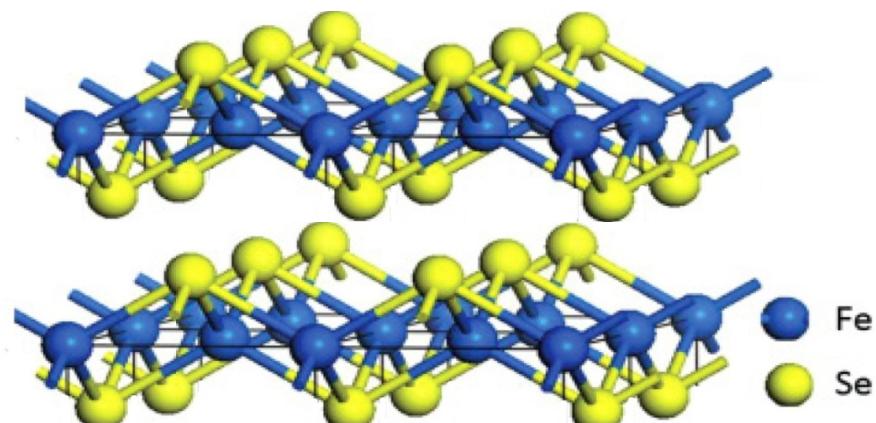
Why is Double-Layer FeSe/SrTiO₃ Difficult to be Doped?

- Charge transfer from oxygen loss in SrTiO_{3-δ};
- Charge transfer is shared by two FeSe layers;
- The more the number of layers, the more difficult to dope.

Single-Layer



Double-Layer



SrTiO₃ Substrate

SrTiO₃ Substrate

Summary

1. Distinct electronic structure of single-layer FeSe superconductor

Hole-like Fermi surface near Γ is not necessary for high- T_c superconductivity in the Fe-based superconductors.

2. Electronic phase diagram of single-layer FeSe/SrTiO₃ established

Two competing and coexisting phases revealed with distinct electronic structures;

Signature of high $T_c \sim 65$ K observed.

3. Insulator-superconductor transition observed in Single-Layer FeSe/SrTiO₃ films

Orbital-selective Mott transition?

4. Dichotomy between single-layer and double-layer FeSe/SrTiO₃ Films

Origin of carrier doping from SrTiO₃ surface.

Thanks